

## Interface enhanced superconductivity at 2D limit and potential to topological superconductivity in 3D Dirac semimetal

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清华高研2015



量子物质科学协同创新中心  
COLLABORATIVE INNOVATION CENTER OF QUANTUM MATTER

Supported by Ministry of  
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China & National Science  
Foundation of China

 **Part I: First direct evidences of high Tc in 0.55 nm thick FeSe films**

*Chin. Phys. Lett. 31, 017401(2014)*

*Highlighted in Editors' Choice: Science 343, 230 (2014)*

*Scientific Reports 4, 6040(2014)*

 **Part II: Detection of a new superconducting phase in 2D limit: a two-atom layer Ga film grown on semiconducting GaN(0001)**

*Physical Review Letters 114, 107003 (2015) (Editors' Suggestion)*

 **Part III: Potential to topological superconductivity in 3D Dirac semimetal**

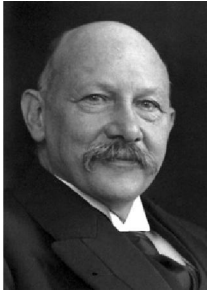
*arXiv:1412.0330*

*arXiv:1501.00418*

# Introduction to superconductivity

## Nobel Prize

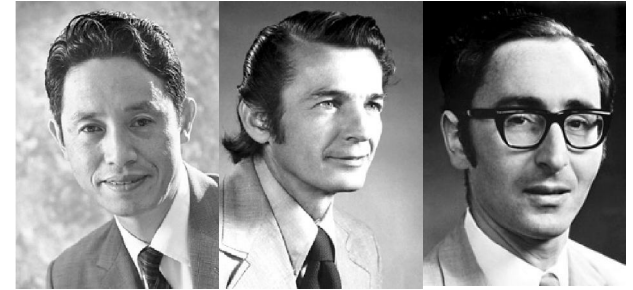
The Nobel Prizes in superconductivity 1913 1972 1973 1987 2003



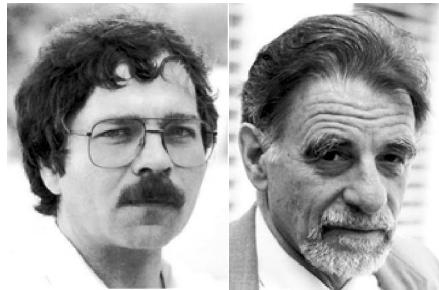
**Heike  
Kamerlingh  
Onnes**



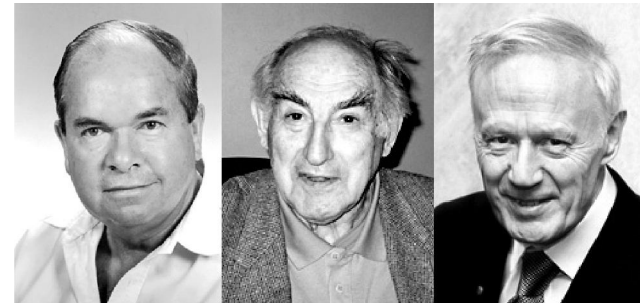
**John Bardeen Leon Neil Cooper  
John Robert Schrieffer**



**Leo Esaki Ivar Giaever  
Brian David Josephson**



**J. Georg Bednorz  
K. Alexander Müller**



**Alexei A. Abrikosov Vitaly L. Ginzburg Anthony J. Leggett**

# What's superconductivity?

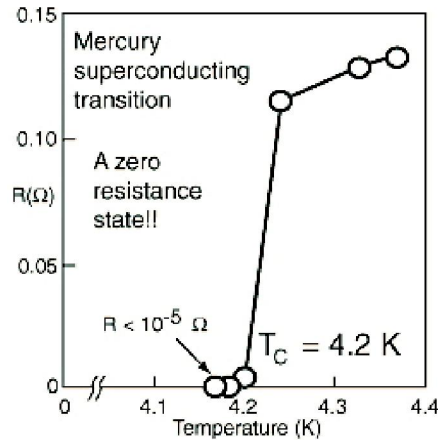
- **Basic Phenomena:**

(i) Disappearance of resistance

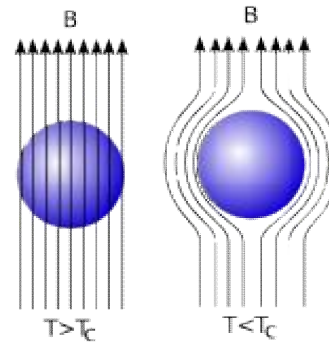
(ii) Perfect Diamagnetism  
(Meissner Effect)



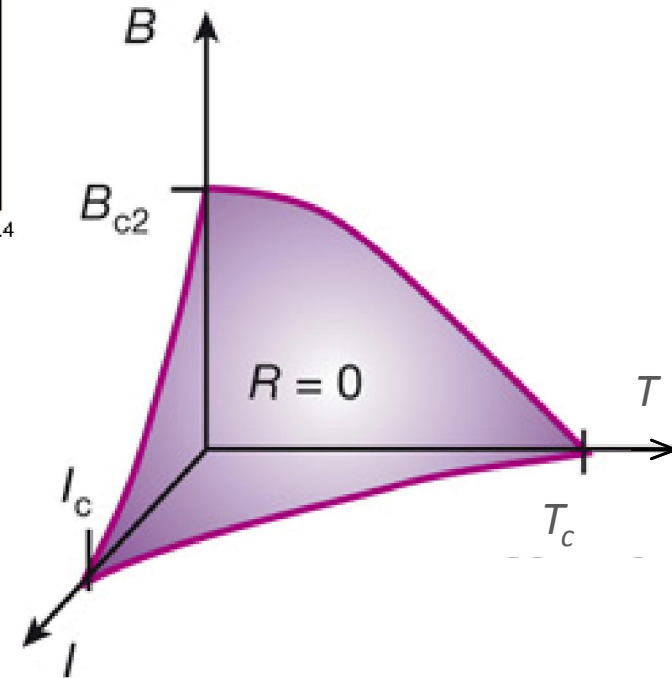
**Kamerlingh-Onnes (1911)**



H. K. Onnes, Commun. Phys. Lab.12,120, (1911)



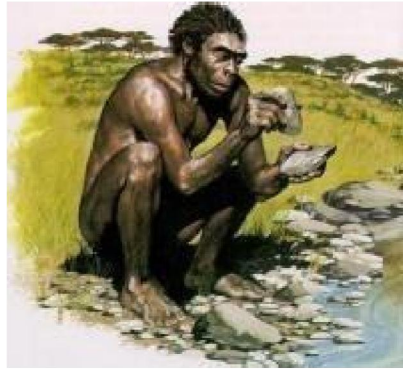
Meissner effect  
(wikipedia)



Superconducting  
Phase Diagram

# Why superconductor important? Human's History

## Stone Age (Insulator Age)



## Iron Age (Conductor Age)



# Today's Mankind

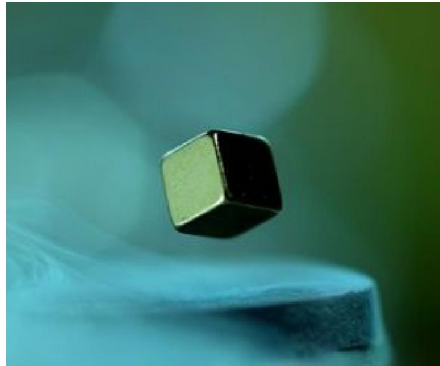


**Information/Semiconductor Age**



# Our Tomorrow: Superconductor Age?

## Superconductor



Dream and Aim

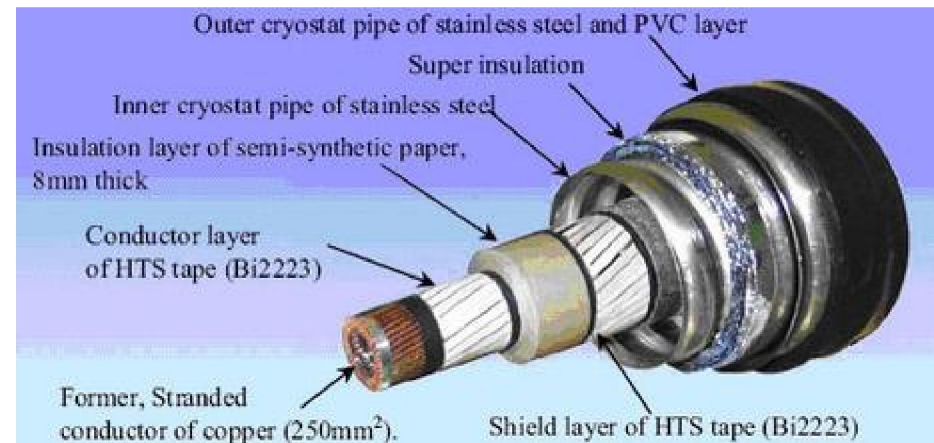
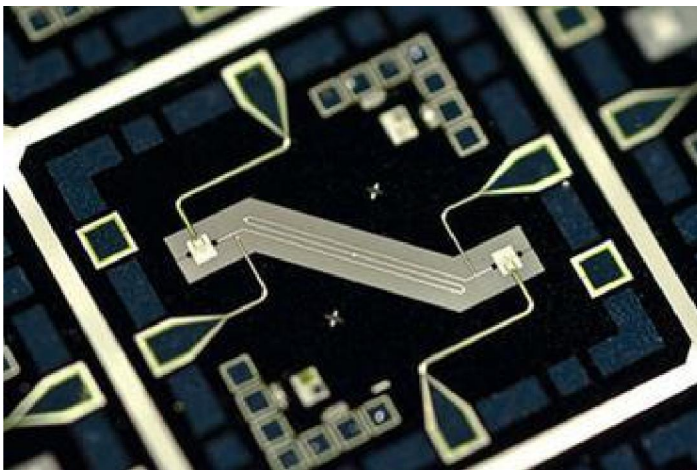


## Room Temperature Superconductor?



*Avatar*

Applications in electronics and electricity:



# Our Tomorrow: Superconductor Age?

Radar, Cannon

军事应用



电磁武器等

医疗设备



MRI、心脑磁图、医用加速器等

高能物理



大型离子加速器、对撞机等

交通、运输



磁浮车、电磁推进系统、升降机等

超导技术的主要应用领域

电子技术、通信



SQUID、低噪声前端放大器、滤波器等

电力、能源



超导电机、输电电缆、变压器、储能飞轮等

机械工程



磁体、磁分离、磁流体控制装置等

Cable

超导电缆



核磁共振成像仪



超导磁悬浮列车



量子计算机



超导磁体



欧洲大型强子对撞机LHC上的ATLAS探测器与超导磁体



SQUID



超导量子比特



手机基站信号接收系统



超导滤波器

Next generation of technology revolution?



# Two-dimensional superconductivity

Let us begin by introducing the specific scales involved and systems of interest. A superconductor with one, two or three dimensions smaller than  $\xi$  is in the quasi-two-dimensional (2D), quasi-one-dimensional (1D) or quasi zero dimensional (0D) regime respectively. For most conventional superconductors,  $\xi$  is of the order of microns. Therefore, systems falling in the 2D, 1D or 0D category are nanoscale systems. According to Hohenberg-Mermin-Wagner theorem (Hohenberg, 1967; Mermin & Wagner 1966), in these reduced dimensionality systems, fluctuations should destroy superconducting order even at low temperature. In 2D samples, the Berezinski-Kosterlitz-Thousless transition occurs, enabling superconducting order to exist at low temperature. However, the existence, limits

*Meenakshi Singh, Yi Sun , **Jian Wang**, "[Superconductivity in nanoscale systems](#)",  
Book chapter of "[Superconductors-Properties, Technology, and Applications](#)", ISBN 979-  
953-307-233-2, InTech - open science | open minds*

Why 2D important?

Our present information technology is based on the “in-plane” fabrication technique.

# Previous achievements in 2D superconductors

## 1. Superconductivity in amorphous films (superconductor insulator transition )

Films Grown on a-Ge Substrates-Homogeneous?(amorphous)

However, no information for morphology and quality of the films due to the technical limitation at that time.

Cyclic evaporation leads to evolution of superconductivity with thickness.

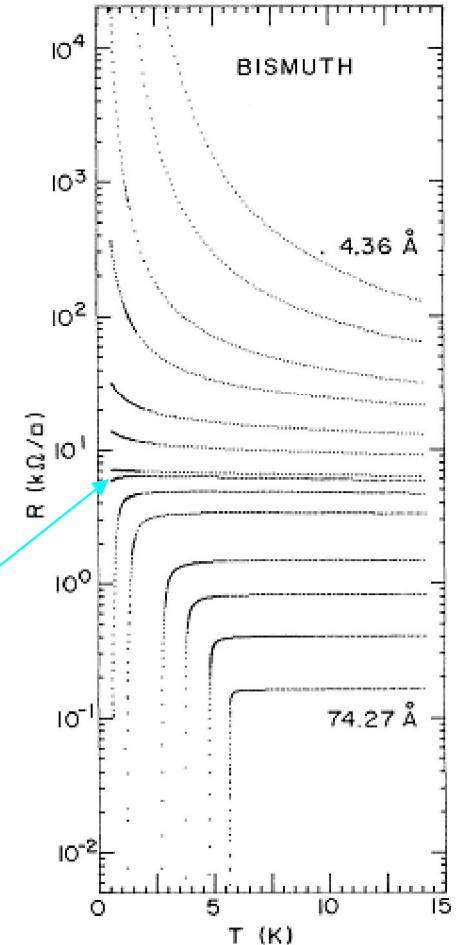
Apparent separation between superconducting and insulating behavior.

Critical resistance close to  $h/4e^2 = 6450 \Omega$

2015 Oliver E. Buckley  
Condensed Matter  
Physics Prize  
Recipient(s):  
[Aharon Kapitulnik](#)  
Stanford University  
[Allen Goldman](#)  
University of Minnesota  
[Arthur Hebard](#)  
University of Florida  
[Matthew Fisher](#)  
University of California,  
Santa Barbara

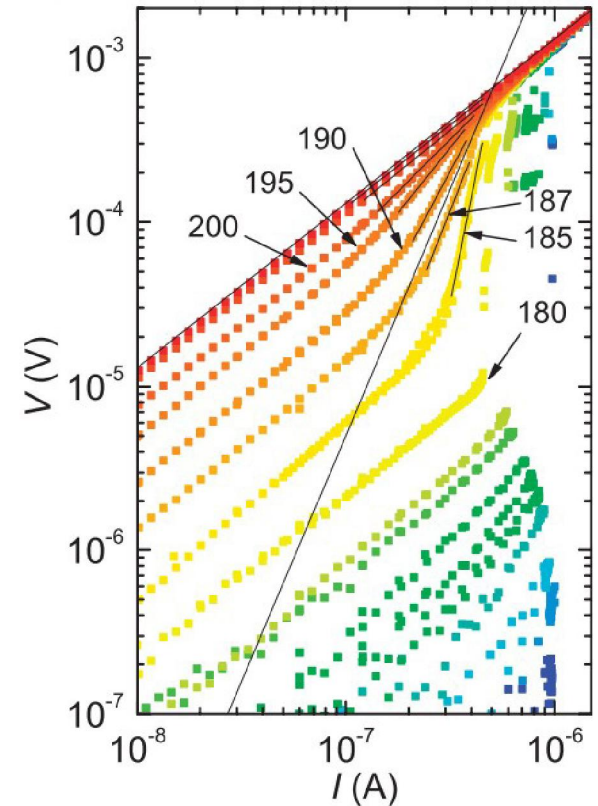
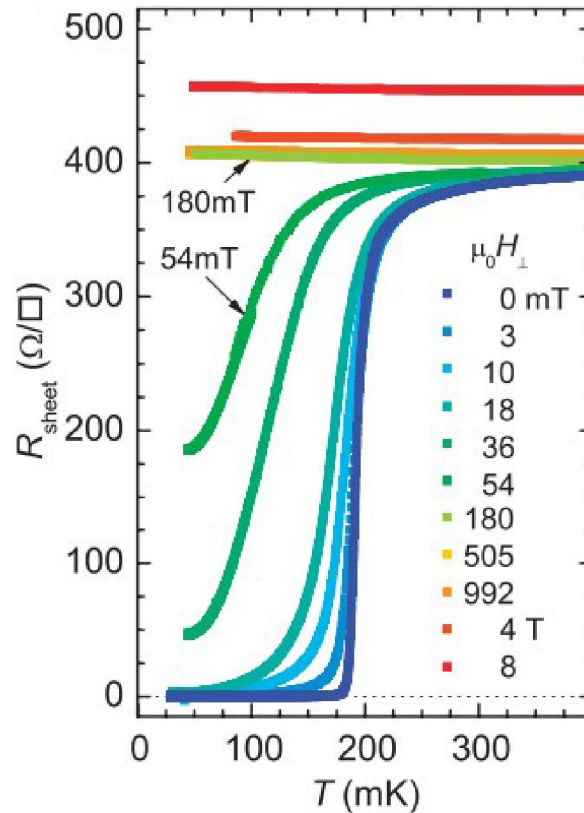
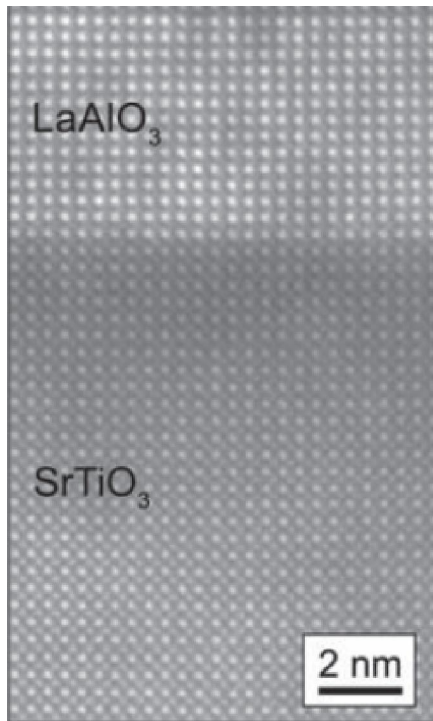
The existence of an unstable fixed point at  $T=0$  separating insulating and superconducting behavior

*Bi film deposited on Ge.  
Film thicknesses shown range from 4.36 to 74.27 Å*



Haviland, Liu, and Goldman  
Phys.Rev.Lett.62,2180(1989)

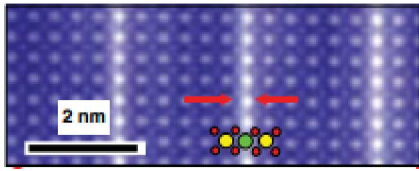
## 2. Interface superconductivity



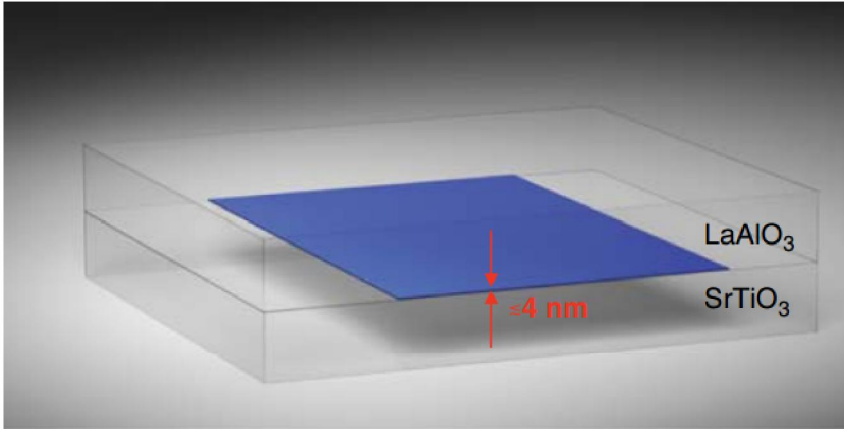
- The electron system at the interface is that of a two-dimensional superconductor;
- The superconducting transition temperature is of 200 mK;
- A clear signature of the BKT transition is found in V-I curves.

Superconductivity at LaAlO<sub>3</sub>/SrTiO<sub>3</sub> interface

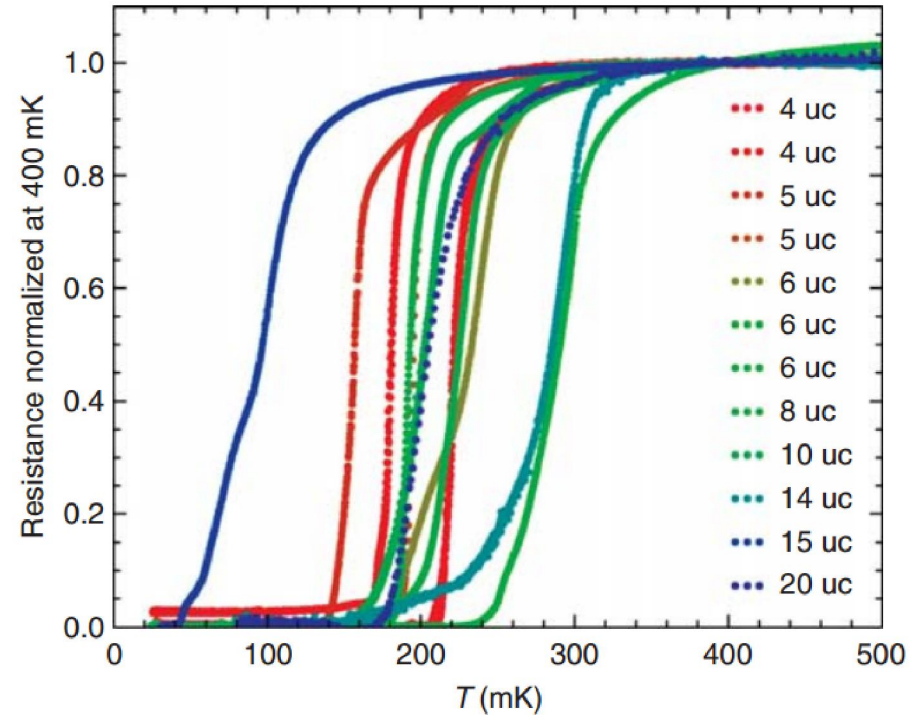
# Superconductivity at LaAlO<sub>3</sub>/SrTiO<sub>3</sub> interface



- The thickness of the superconducting sheet is estimated to be less than **~4 nm**.



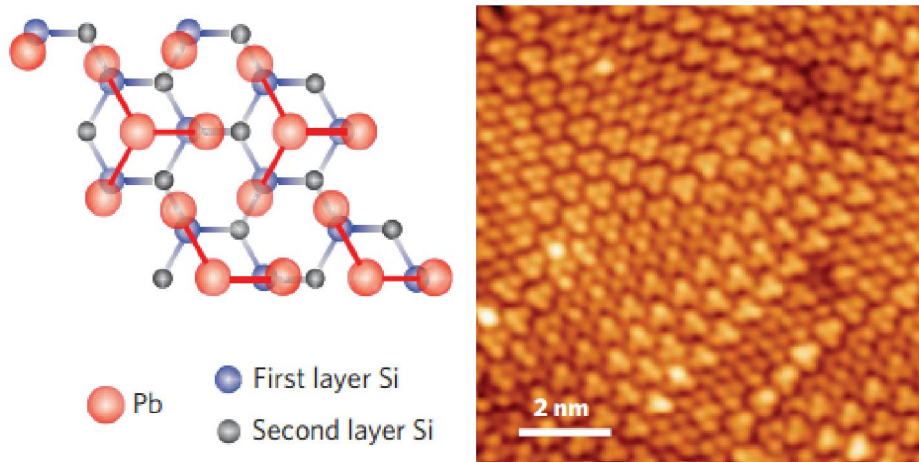
- In such samples, a superconducting transition with a critical temperature of **~ 200 mK** is commonly observed.



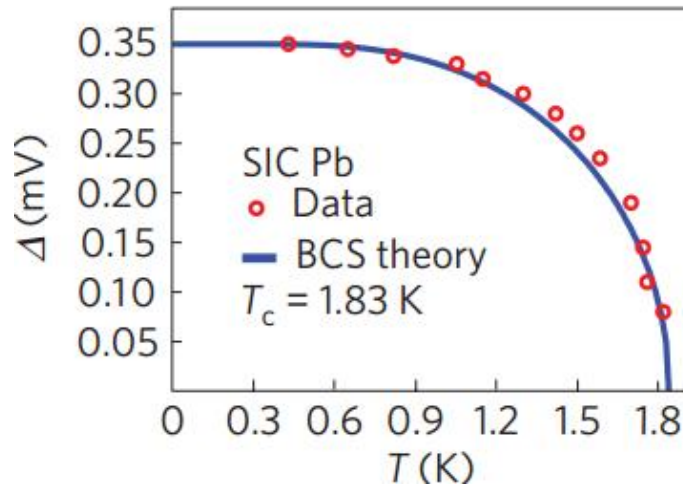
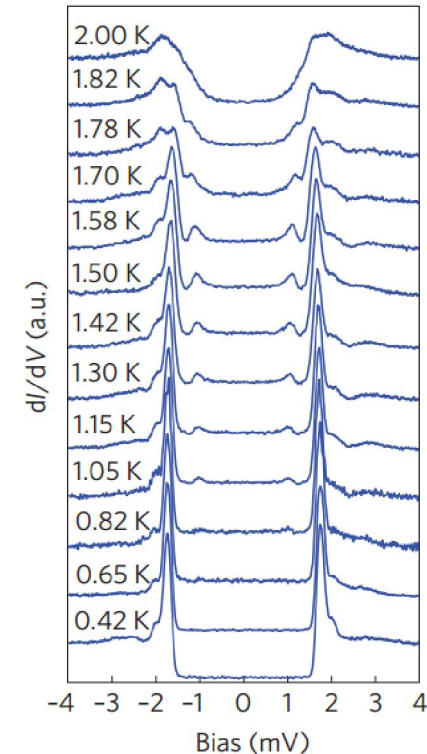
**T<sub>c</sub> is too low and the thickness of superconducting layer is 4 nm, which may be beyond 2D limit.**

# 3. Superconductivity in the thinnest single crystalline films

## Superconductivity in one-atomic-layer Pb film



Atomic structural model and High-resolution STM images of the striped incommensurate -Pb



- The film shows a superconducting transition temperature of 1.83 K for an atom areal density  $n_s = 10.44$  Pb atoms  $\text{nm}^{-2}$ . ( $T_c$  of bulk Pb is 7.2 K)

Zhang *et al.*, Nature Physics 6, 104 (2010)

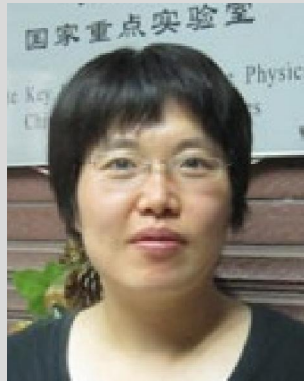
# Part I: Direct evidence of high $T_c$ in 0.55 nm thick FeSe film

## Major Collaborators:

### Tsinghua University



Prof. Qi-Kun Xue



Prof. Lili Wang

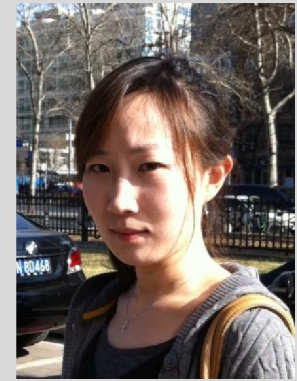


Prof. Xucun Ma



Dr. W. Zhang

### Peking University

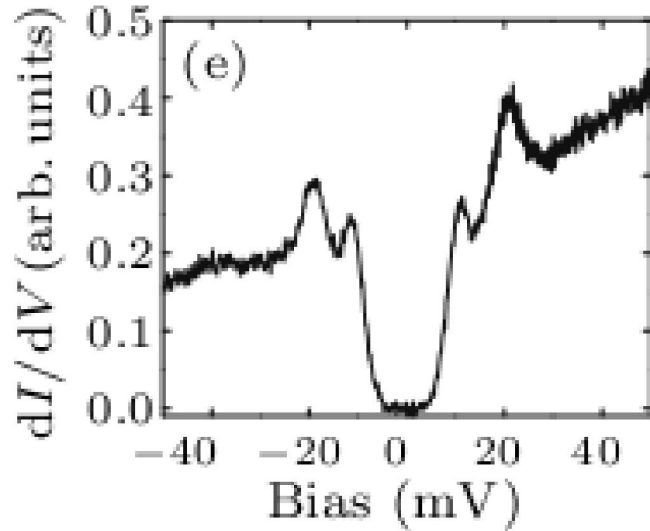


Dr. Yi Sun

**Other collaborators:** ZHANG Jin-Song, LI Fang-Sen, GUO Ming-Hua, ZHAO Yan-Fei, ZHANG Hui-Min, PENG Jun-Ping, XING Ying, WANG Hui-Chao, FUJITA Takeshi, HIRATA Akihiko, LI Zhi, DING Hao, TANG Chen-Jia, WANG Meng, WANG Qing-Yan, HE Ke, JI Shuai-Hua, CHEN Xi, WANG Jun-Feng, XIA Zheng-Cai, LI Liang, WANG Ya-Yu, CHEN Ming-Wei

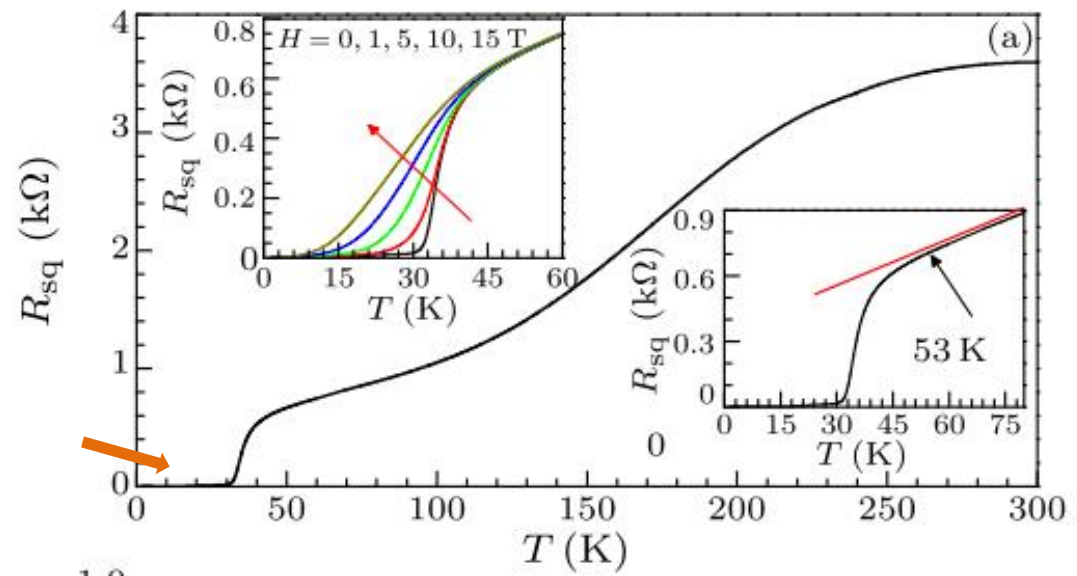
# Previous studies in one unit cell (1UC) FeSe film on STO substrate:

Qi-Kun Xue Team: Chin. Phys. Lett. 29, 037402 (2012)

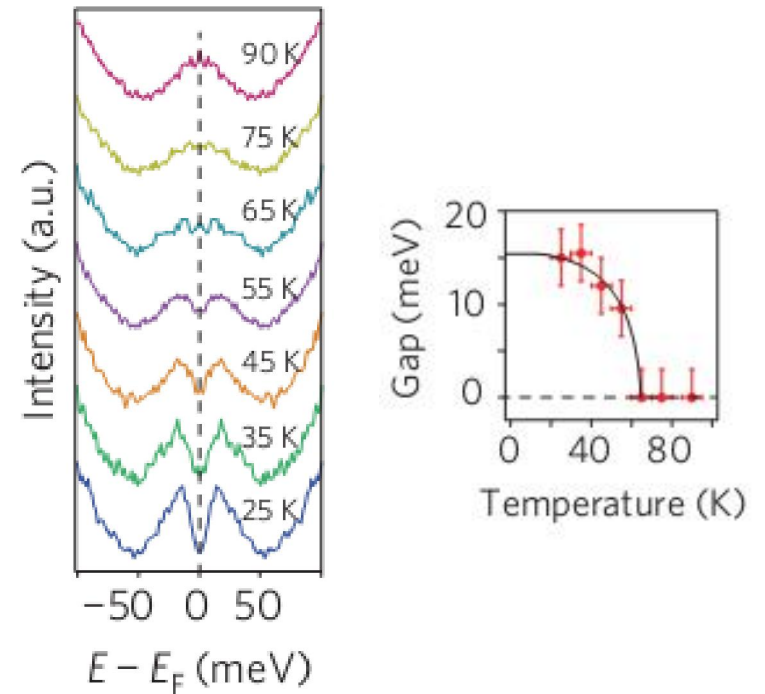
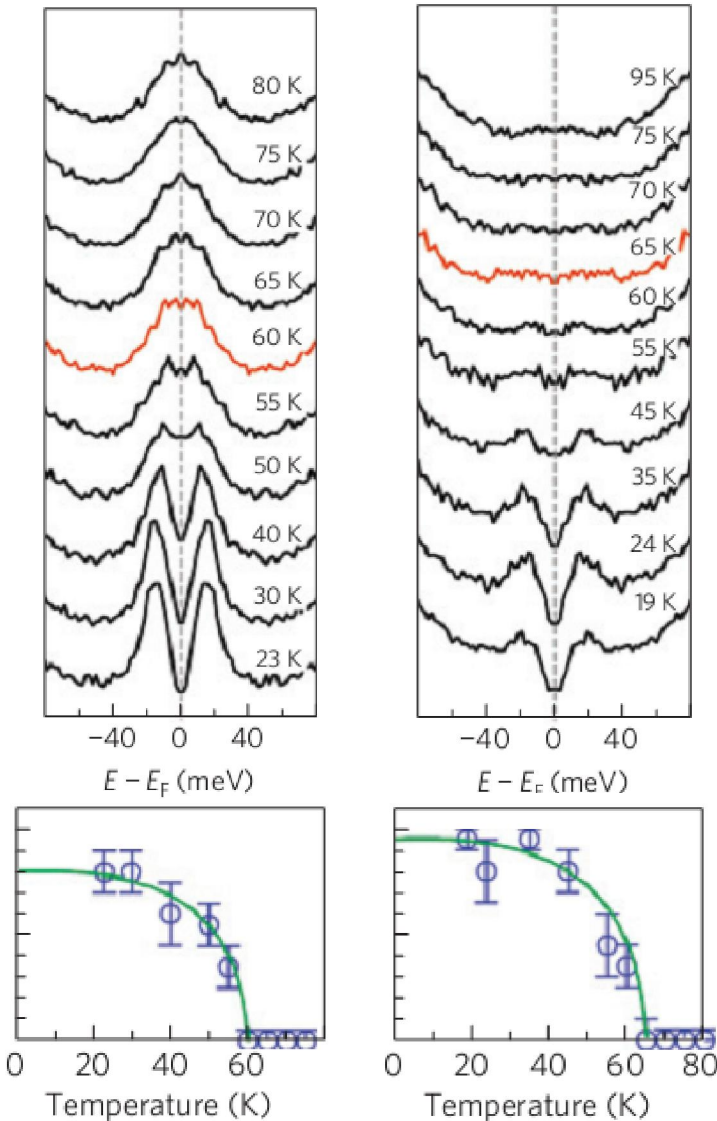


**1UC-FeSe film on Nb-doped STO substrate**  
**The large superconducting-like gap  $\Delta=20.1$  meV by STM**

## 5UC-FeSe film with Si capping layer



**Small residual resistance**



**Single-layer FeSe films grown on SrTiO<sub>3</sub> substrates by ARPES:**

**Estimated  
T<sub>c</sub> ~ 65 K ± 5K**

**Is the gap real  
superconducting gap?**

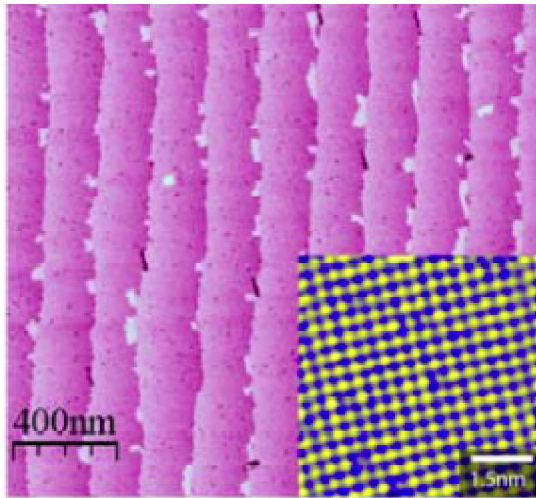
***X. J. Zhou: Nature Mater. 12, 605 (2013).  
D. L. Feng: Nature Mater. 12, 634 (2013).***



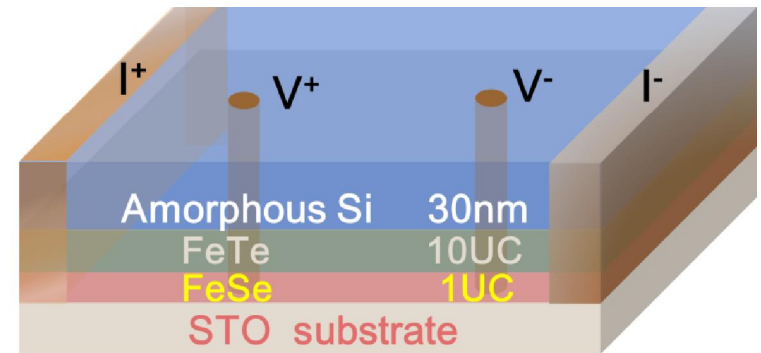
**The Greatest Challenge: direct transport and Meissner effect evidences for high  $T_c$  in 1 UC (0.55nm) thick FeSe films!**

Our work was to achieve direct transport and Meissner effect evidences for high  $T_c$  1 UC (0.55nm) thick FeSe films!

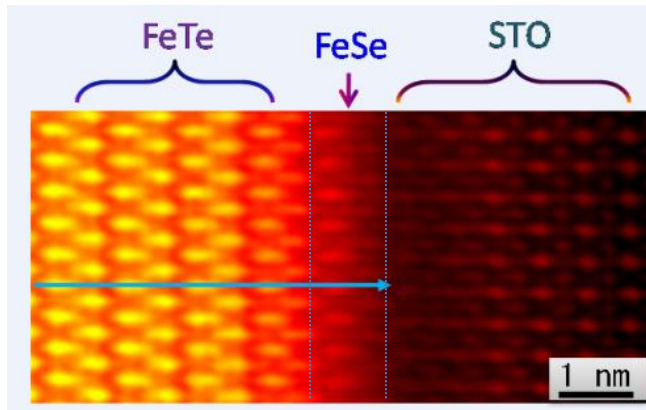
Is it possible to measure 1UC FeSe by *ex situ* measurements?



STM image of atomic flat FeSe film grown in ultrahigh vacuum (UHV) chamber



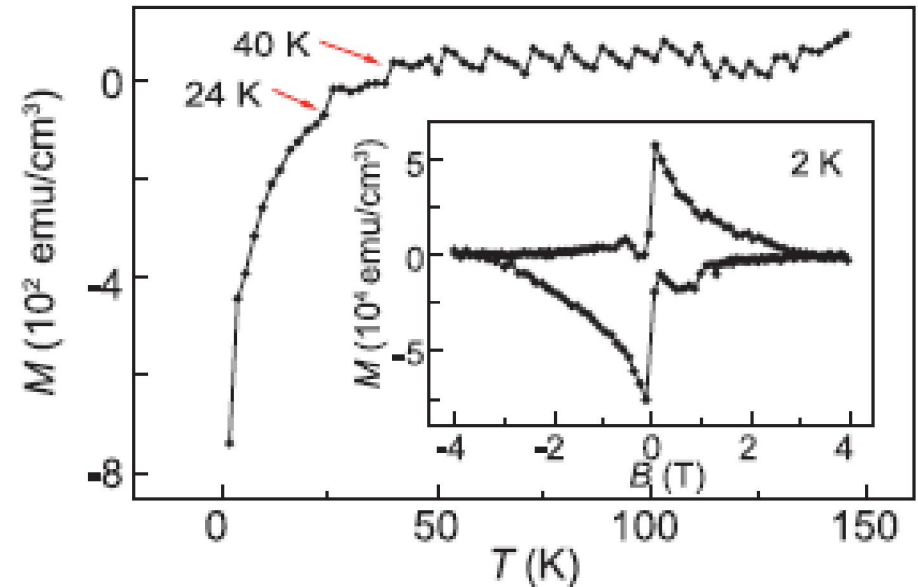
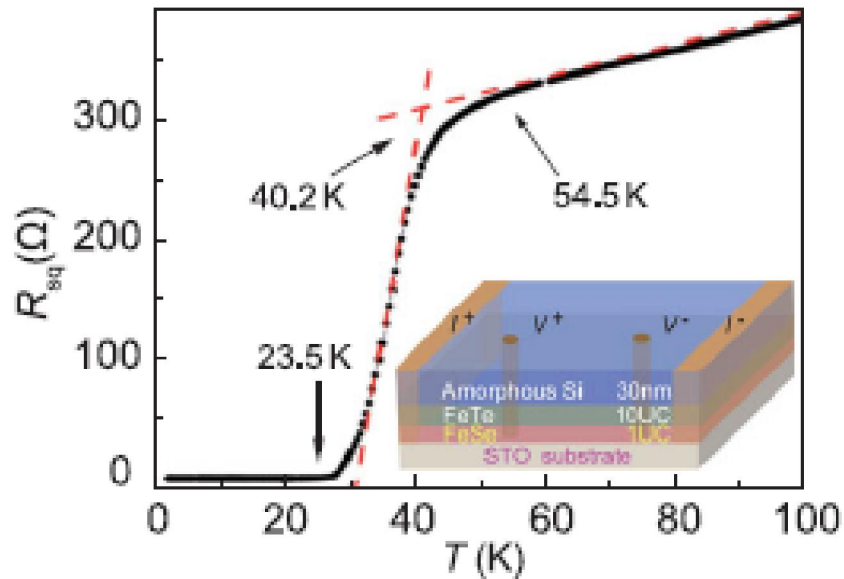
A schematic structure for *ex situ* measurements



TEM image of 0.55 nm thick FeSe film with FeTe protection layer

# First direct evidence of superconductivity in 0.55nm thick FeSe films on insulating STO: extremely interface enhanced superconductivity

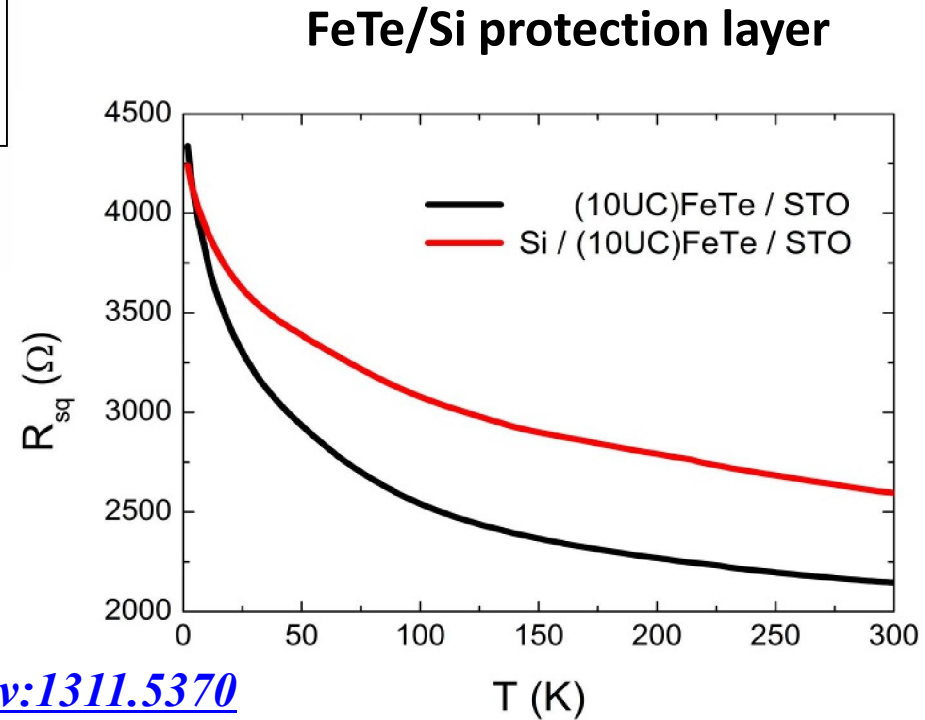
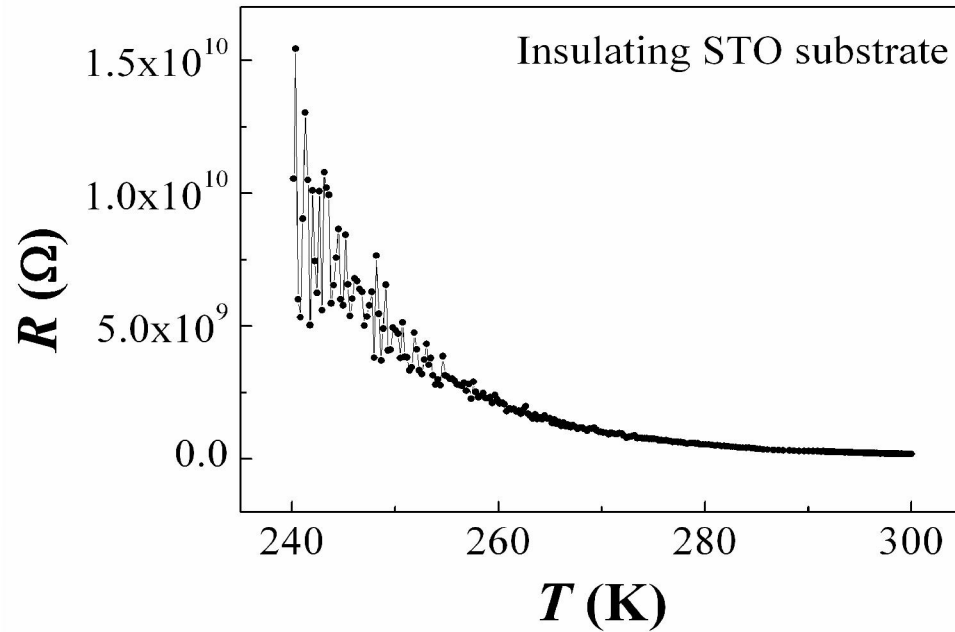
**We might be first group to obtain Meissner effect in such thin superconducting films!**



The onset  $T_c$  of 0.55 nm FeSe is **above 40 K (high  $T_c$ )**, which is **five times larger** than that of bulk FeSe.

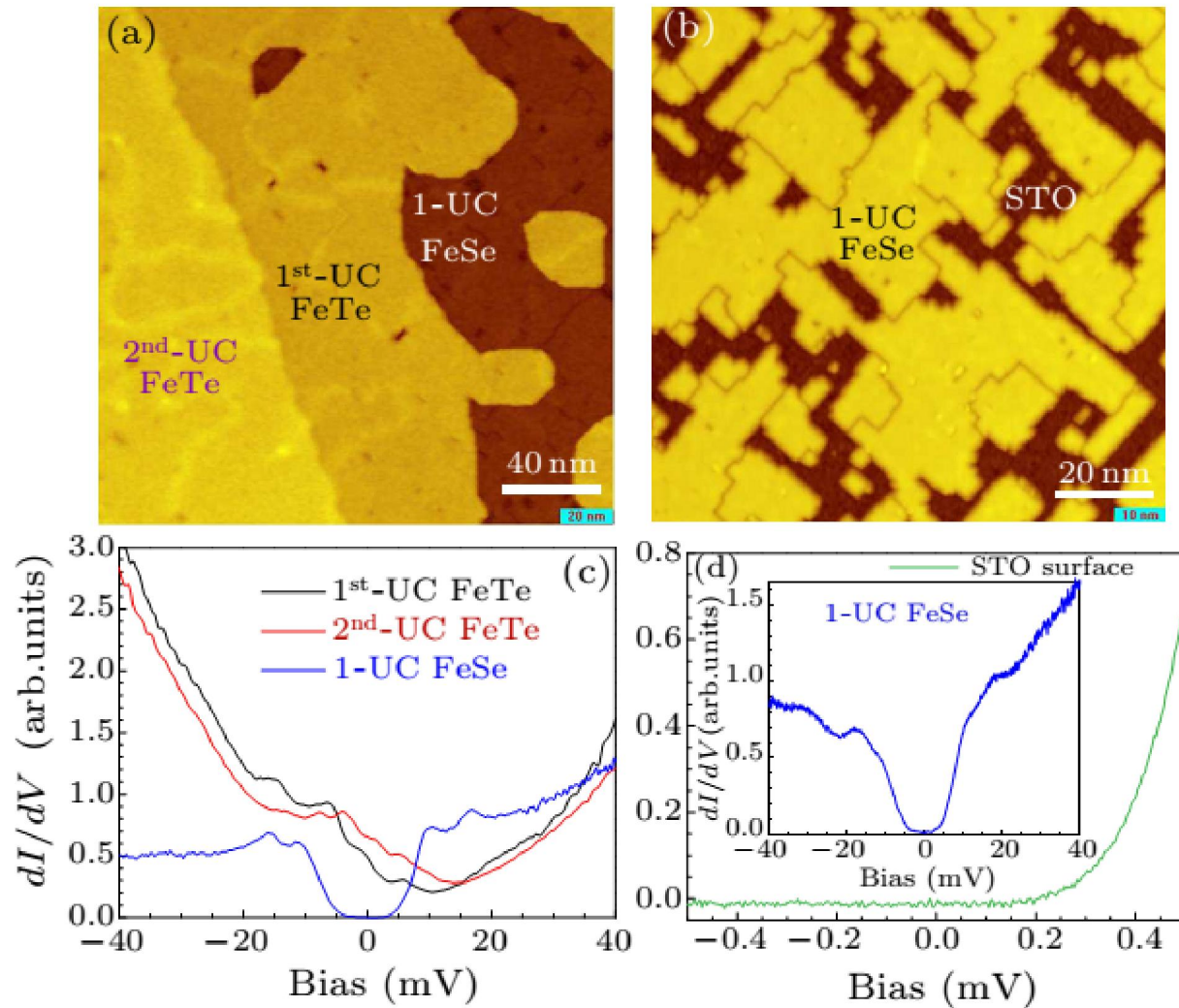
Transport and Magnetization measurements show the **zero resistance and Meissner effect**, which are direct evidences of superconductivity.

The superconducting layer is limited in 0.55 nm thick FeSe film.



*CHIN. PHYS. LETT.* 31, 017401(2014); [arXiv:1311.5370](https://arxiv.org/abs/1311.5370)

Proximity effect cannot make the FeTe layer and STO top surface superconducting.

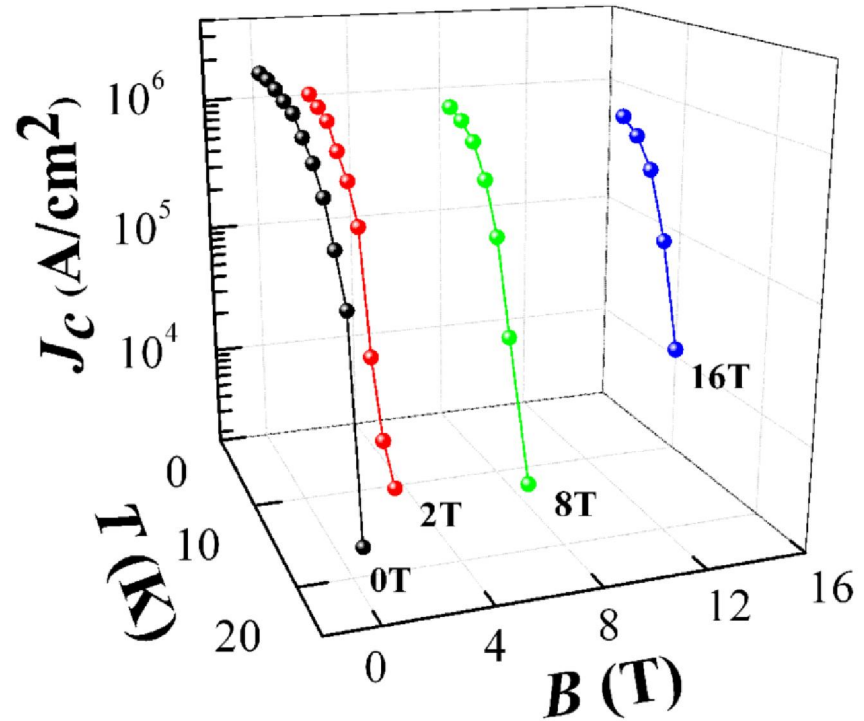
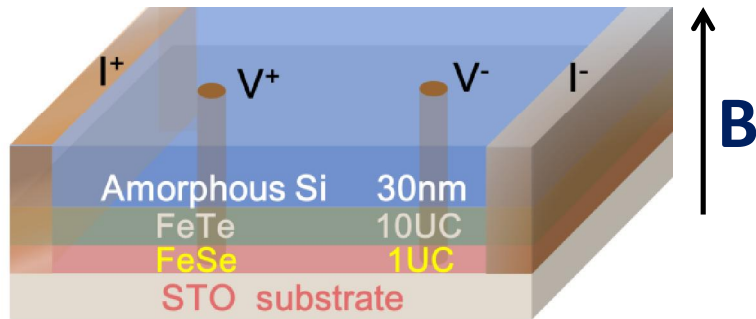


The evidence of charge transfer?

*CHIN. PHYS. LETT.* 31, 017401(2014); [arXiv:1311.5370](https://arxiv.org/abs/1311.5370)

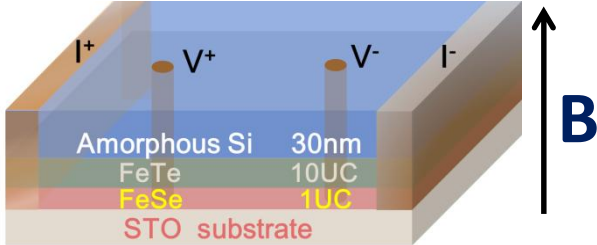
# 0.55 nm thick FeSe superconducting layer: the thinnest high $T_c$ superconductor

We demonstrated the superconducting layer is limited in 1 UC FeSe, i.e. 0.55nm thick layer.



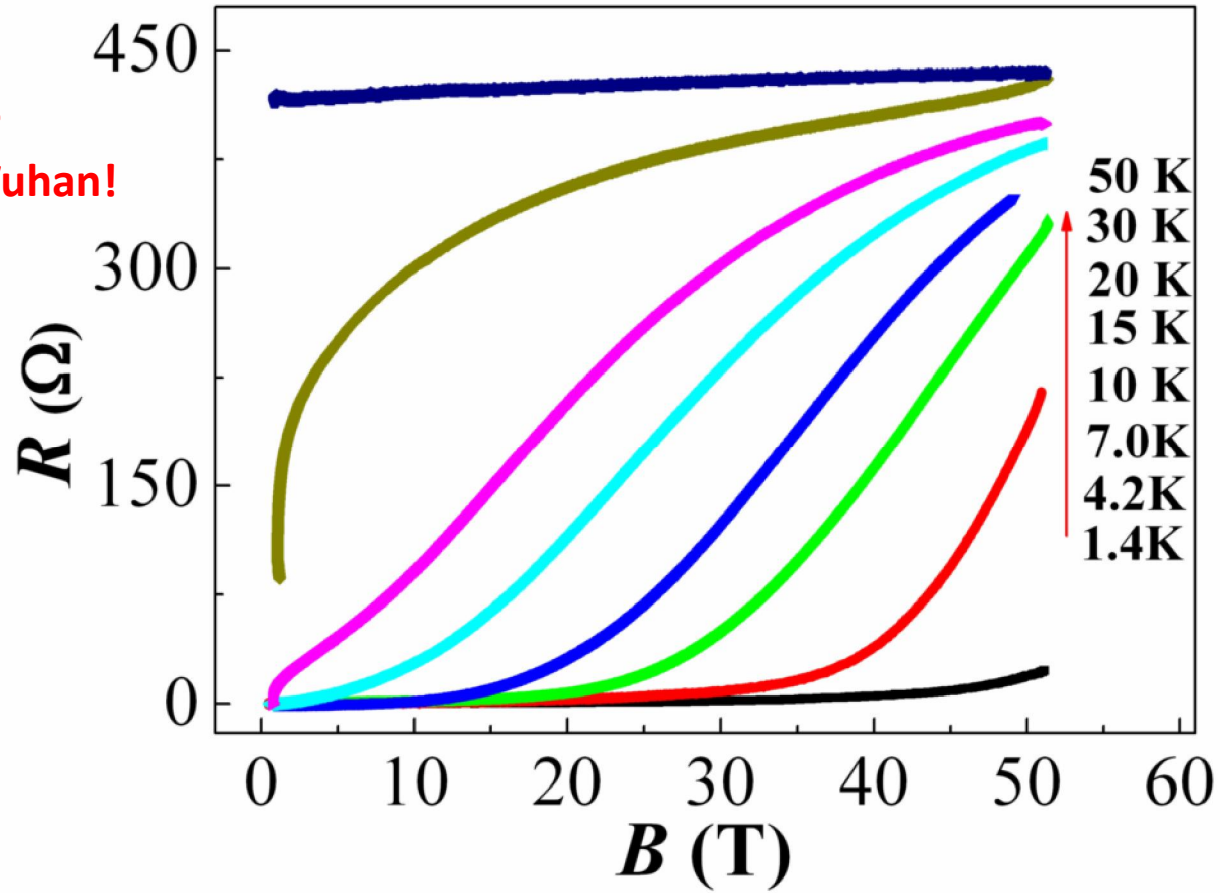
Below 12 K, the critical current density  $J_c$  of the film is always larger than  $1 \times 10^6 \text{ A/cm}^2$ , which is two orders of magnitude higher than that of bulk FeSe ( $10^4 \text{ A/cm}^2$  at 1.8 K)

*CHIN. PHYS. LETT.* 31, 017401(2014); [arXiv:1311.5370](https://arxiv.org/abs/1311.5370)

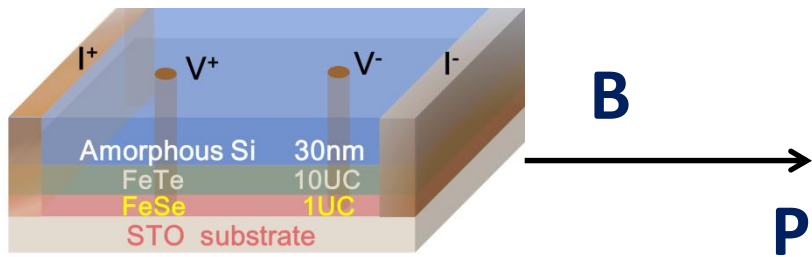


# Pulsed Magnetic Field @Wuhan

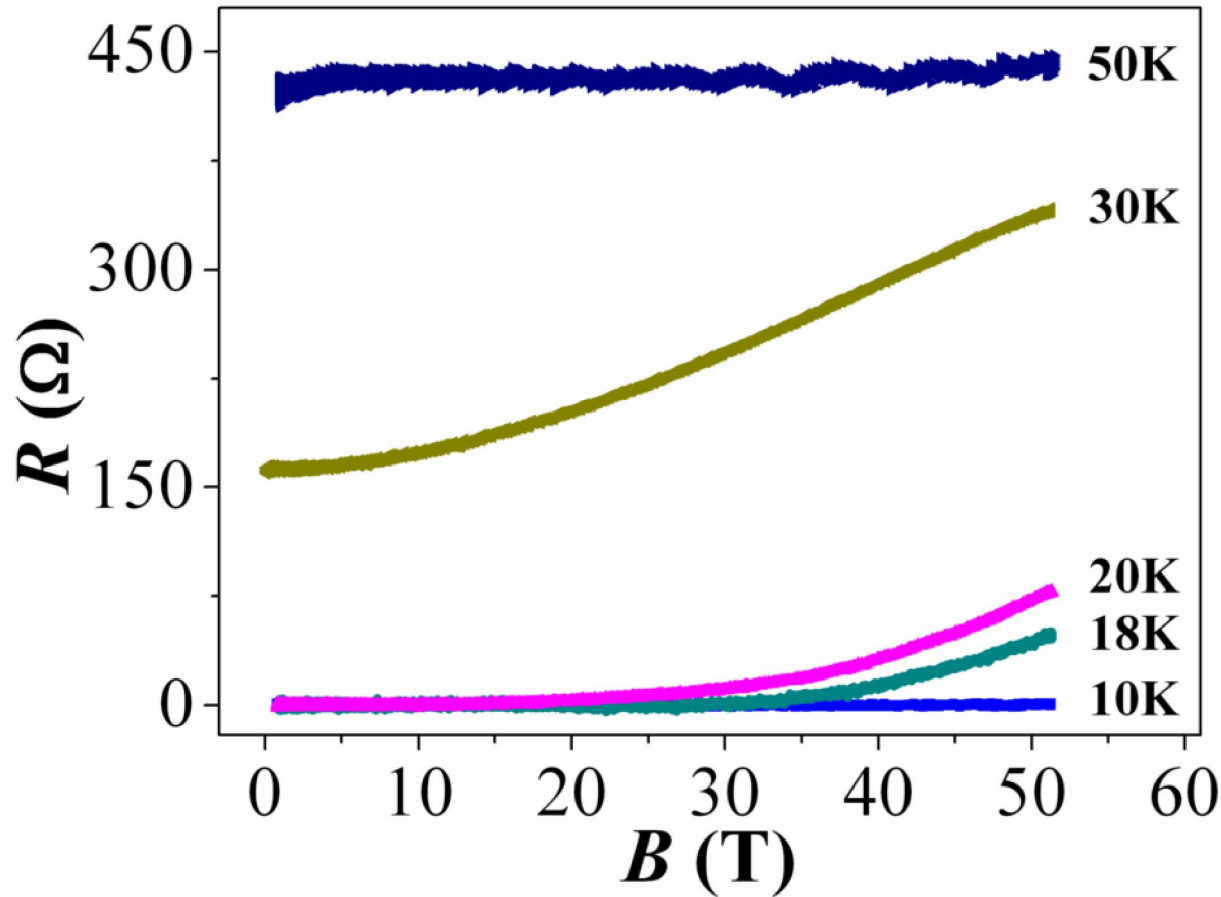
We are the first user of high field lab @Wuhan!



The resistance is significantly lower than the normal state value even at **52 T** unless for temperatures close to  $T_c$ .  
At **1.4 K**, the resistance maintains zero up to 40 T.



## Pulsed Magnetic Field



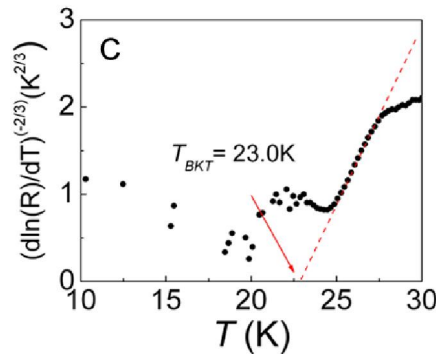
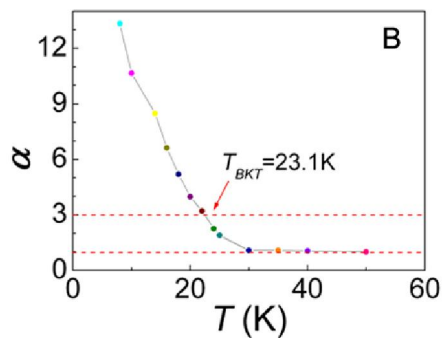
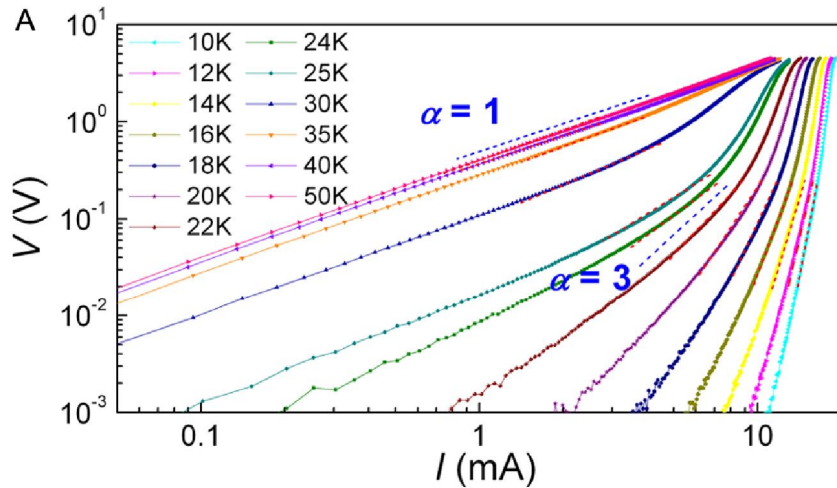
**A signature of  
2D Superconductivity**

**In parallel field, the zero resistance state persists at a magnetic field up to 52 T and a temperature of 10 K.**



# BKT-like phase transition was observed, which may show another signature of 2D superconductivity

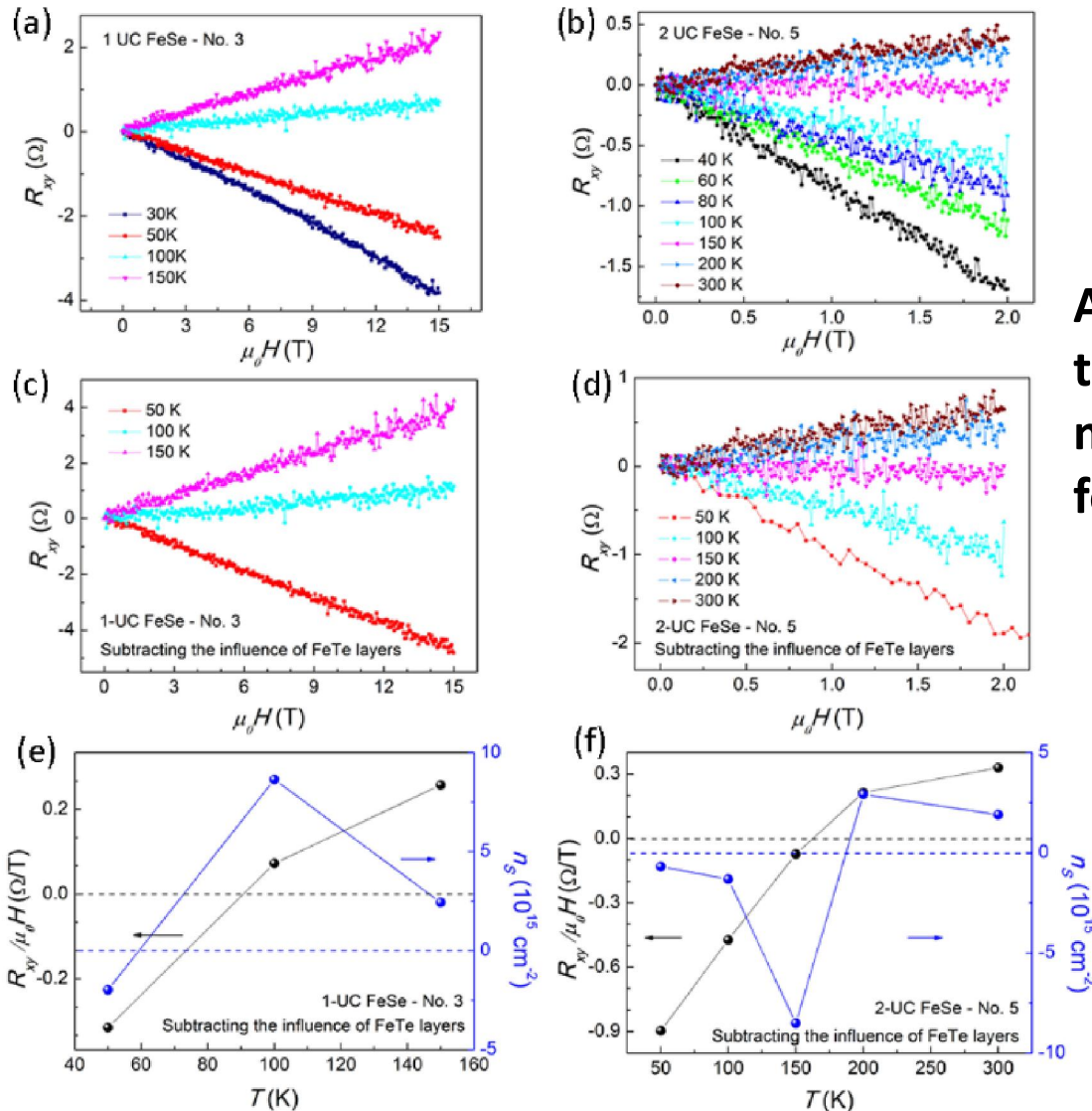
At the BKT transition, the current-induced Lorentz force results in a  $V \sim I^\alpha$  behavior, with  $\alpha(T_{BKT}) = 3$



It was predicted that if the superconducting transition of a 2D film is governed by the BKT process, the resistance near the transition temperature  $T_{BKT}$  will show a temperature dependence of the form,

$$R(T) = R_0 \exp[-b(T / T_{BKT} - 1)^{-1/2}]$$

For 1-UC and 2-UC FeSe films on insulating STO substrates,  
the information of carrier density above  $T_c$  can be obtained by Hall measurement:



A crossover from p type  
to n type is observed, which  
might be a necessary transform  
for observed high  $T_c$ .

More parameters and  
detailed information,  
please see:

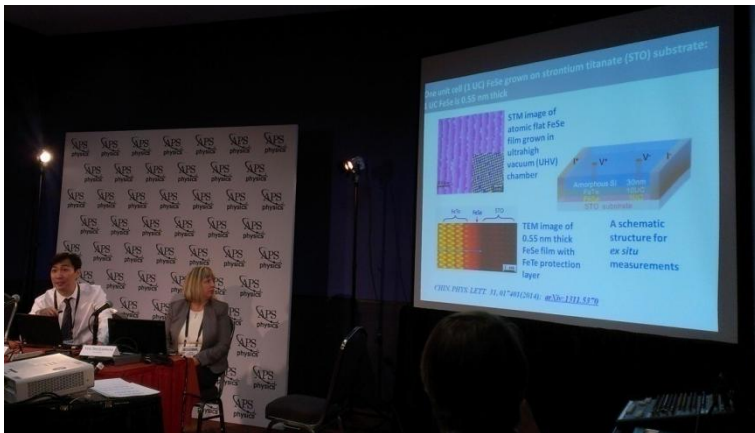
Y. Sun *et al.*, Scientific  
Reports, 4, 6040 (2014)

[arXiv:1404.3464](https://arxiv.org/abs/1404.3464)

# Direct Observation of High-Temperature Superconductivity in One-Unit-Cell FeSe Films \*

Our first transport and Meissner effect evidences of high  $T_c$  superconductivity in 1 UC FeSe film were published in **CHIN. PHYS. LETT. 31, 017401(2014)**  
[arXiv:1311.5370](https://arxiv.org/abs/1311.5370)

A press conference  
 at 2015 March Meeting



Environmental Protection Agency Air Quality System for 1999–2008, Meng *et al.* investigated the relationship between PbA and PbB since the phase-out of leaded gasoline. They found that the emission sources for lead have changed,



leading to a shift from a fine to a coarse PbA particle size distribution, and show that PbA in coarse airborne particles is a statistically significant predictor of PbB. The PbB levels of children are more sensitive to changes in PbA concentrations than are those of adults. — JFU

*Environ. Sci. Technol.* 10.1021/es4039825 (2013).

Highlighted in Editors' Choice: Science 343, 230 (2014)

## PHYSICS

### A Very Thin Superconductor

Manipulating the dimensionality of materials can lead to profound changes in their electronic properties. The iron-based superconductor FeSe has a relatively low superconducting transition temperature  $T_c$  of about 8 K in the bulk; however, spectroscopic measurements have suggested that a single-unit-cell layer of this material has a much higher  $T_c$ . Transport measurements needed to confirm this finding proved challenging; now, Zhang *et al.* overcome these difficulties by growing the FeSe layer on a  $\text{SrTiO}_3$  substrate and capping it with FeTe, with an additional layer of Si deposited on top of the FeTe to prevent its exposure to air. By measuring the electrical resistance as a function of temperature, they detected the onset of superconductivity at a temperature higher than 40 K; the critical current density, important for practical applications, was much higher than in the bulk. Because neither the substrate nor the capping layer exhibited superconductivity, and the transport characteristics power laws were consistent with the Berezinskii-Kosterlitz-Thouless transition, the superconductivity appears to be a genuine property of the FeSe layer and has a two-dimensional nature. Because of its relative simplicity, the system presents a good testing ground for unconventional superconductivity. — JS

*Chin. Phys. Lett.* 31, 017401 (2014).

# 美国物理学会的《物理》介绍的2015 March Meeting看点

## Notes from the Editors: Snapshots from the 2015 APS March Meeting

Published March 19, 2015 | Physics 8, 25 (2015) | DOI: 10.1103/Physics.8.25

Researchers from industry, universities, and major labs gathered at the annual APS March meeting held in San Antonio, Texas. Here's a selection of this year's presentations.

### Hints to High- $T_c$ Superconductivity from a Thin Material?

Researchers still don't know why superconductivity occurs in iron-based compounds—materials that, like cuprates, superconduct at a relatively high temperature. Perhaps answers will come from the recent, and surprising, finding that a single unit cell of FeSe, grown on the insulator SrTiO<sub>3</sub>, superconducts at a temperature five times higher than its bulk form does. Speaking at a session on [superconductivity in two-dimensional materials](#), Jian Wang of Peking University gave an overview of his measurements, first reported in 2014, showing that a 0.55-nanometer-thick layer of FeSe has an onset of superconductivity around 50 kelvin (K), compared to 8 K for bulk FeSe.

A huge and expensive research effort—almost entirely based in China—is underway to make new samples and explain the effect, which was first seen in surface spectroscopy measurements. In November, researchers at Jiao Tong University in Shanghai [reported](#) that they had seen the resistivity of FeSe on SrTiO<sub>3</sub> plunge to zero at 109 K. If it can be reproduced by other groups, the result would “change our entire view” of high-temperature superconductivity, said Ivan Bozovic of Brookhaven National Laboratory in a phone call. He said the result is important because the electronic structure of FeSe on SrTiO<sub>3</sub> is so much simpler than it is in bulk iron compounds or in the cuprates. If one mechanism explains all three systems—and Bozovic hopes it does—it would suggest that the complex electronic structure of the cuprates and iron compounds isn't essential for high-temperature superconductivity. (See [this commentary](#) in *Nature Physics* from Bozovic and Charles Ahn of Yale University.)

—Jessica Thomas and Katherine Wright

[Previous Editorial](#) | [Next Editorial](#)

# Summary

- We identified **high T<sub>c</sub> in 1 UC FeSe** on STO, which reveals the way that by **interface engineering**, the superconductivity in ultrathin layer can be **extremely enhanced**. Our discovery also offers an aspect to understand high T<sub>c</sub> superconductivity based on two dimensional or interface superconductors.
- **The macroscopic area** of ultrathin high T<sub>c</sub> superconducting FeSe film on **gating easily substrate** STO shows great potential for application in superconducting nanoelectronics or electronic devices, such as FET and SQUID.

For more details:

**CHIN. PHYS. LETT. 31, 017401 (2014) ([arXiv:1311.5370](#))**

**Highlighted in Editors' Choice: Science 343, 230 (2014)**

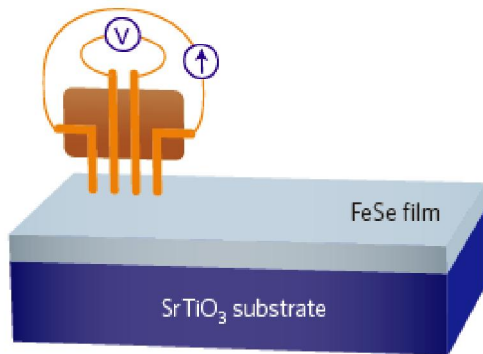
# A new frontier for superconductivity

Ivan Bozovic and Charles Ahn [A brief review for 1 UC FeSe: Nature Physics 10, 892 \(2014\)](#)

Monolayer films of iron selenide deposited on strontium titanate display signatures of superconductivity at temperatures as high as 109K. These recent developments may herald a flurry of exciting findings concerning superconductivity at interfaces.

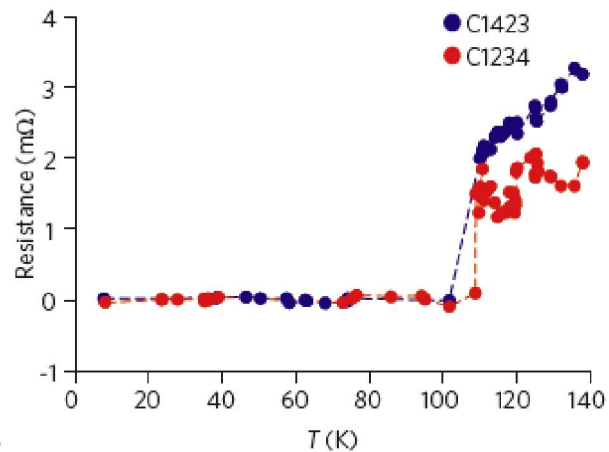
**Two indications of  $T_c$  above nitrogen temperature in 1 UC FeSe are reviewed in this paper.**

a

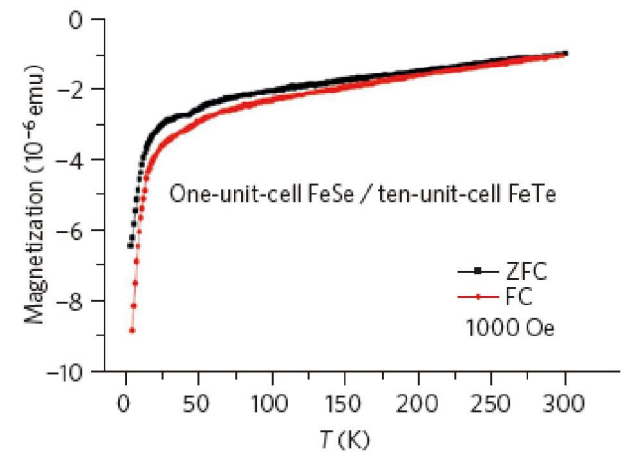


Local four-tip measurement

b



c



Shanghai Jiaotong University


[DOI:10.1038/NMAT4153](https://doi.org/10.1038/NMAT4153)

[Scientific Reports 4, 6040 \(2014\) \(arXiv:1404.3464\)](#)

**More reliable experiments are necessary!**

# Future Research Direction and Perspective

- **Is 1 UC FeSe the other superconducting system above liquid nitrogen temperature besides cuprates?** We need further increase the quality of 1 UC FeSe film, try different substrates and develop better protection layer to detect if  $T_c$  of 1 UC FeSe can be higher than 77 K by *in situ* and *ex situ* transport and Meissner effect measurements.
- **Stimulated by the observation of high  $T_c$  in 1 UC FeSe,** we can try various one unit cell metallic or superconducting films on different ceramic or semiconducting substrates to search for new extremely interface enhanced 2D superconductors, especially for high  $T_c$  and even for long-term pursuit room temperature superconductors.

 **Part II: Detection of a new superconducting phase in 2D limit:  
a two-atom layer Ga film grown on semiconducting GaN(0001)**  
*Physical Review Letters 114, 107003 (2015) (Editors' Suggestion)*



# Acknowledgments

## Major Collaborators:

### Tsinghua University and Institute of Physics



Prof. Qi-Kun Xue



Prof. Xucun Ma

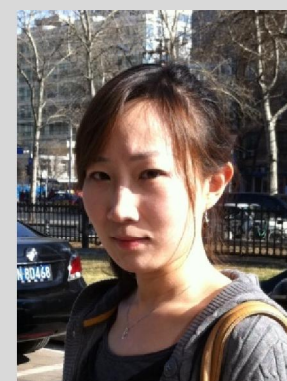


Huimin Zhang



Dr. Wei Li

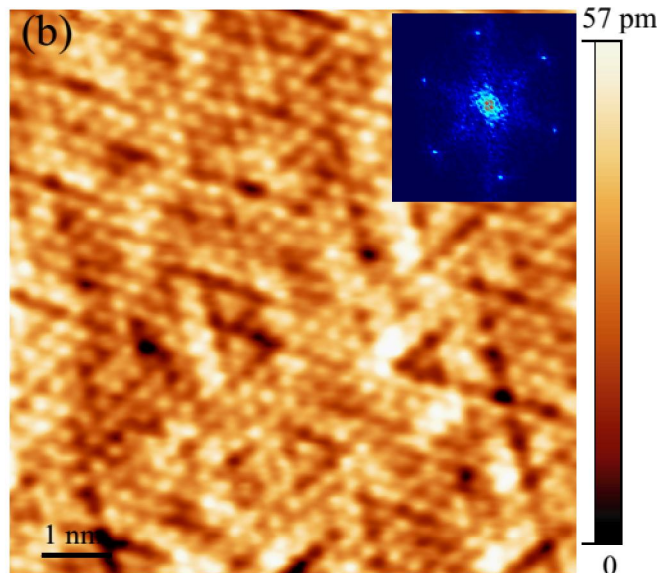
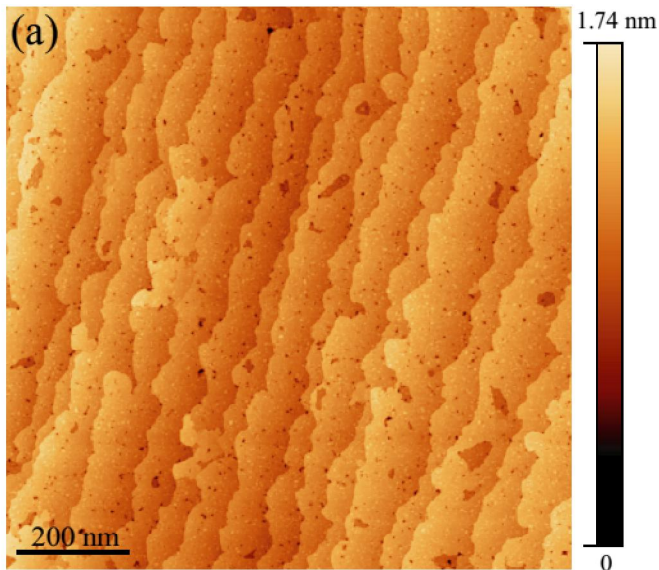
### Peking University



Dr. Yi Sun

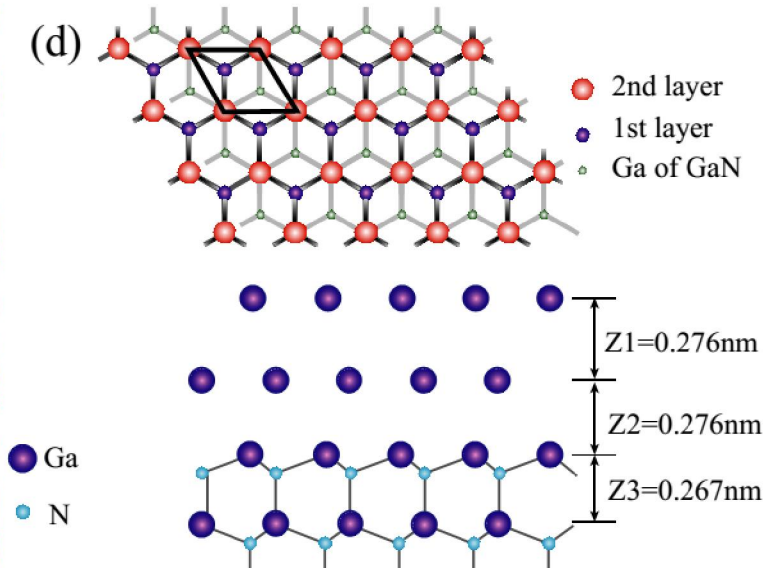
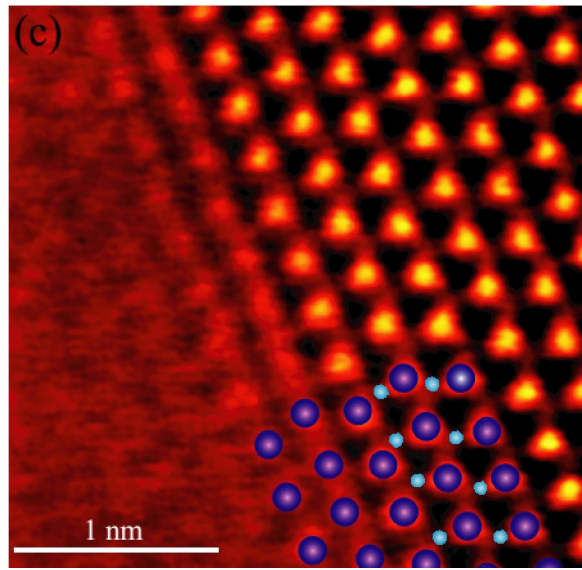
**Other collaborators:** Jun-Ping Peng, Can-Li Song, Ying Xing, Qinghua Zhang, Jiaqi Guan, Zhi Li, Yanfei Zhao, Shuaihua Ji, Lili Wang, Ke He, Xi Chen, Lin Gu, Langsheng Ling, Mingliang Tian, Lian Li, X. C. Xie, Jianping Liu, Hui Yang

# Two-atom layer Ga film grown on GaN(0001) by MBE



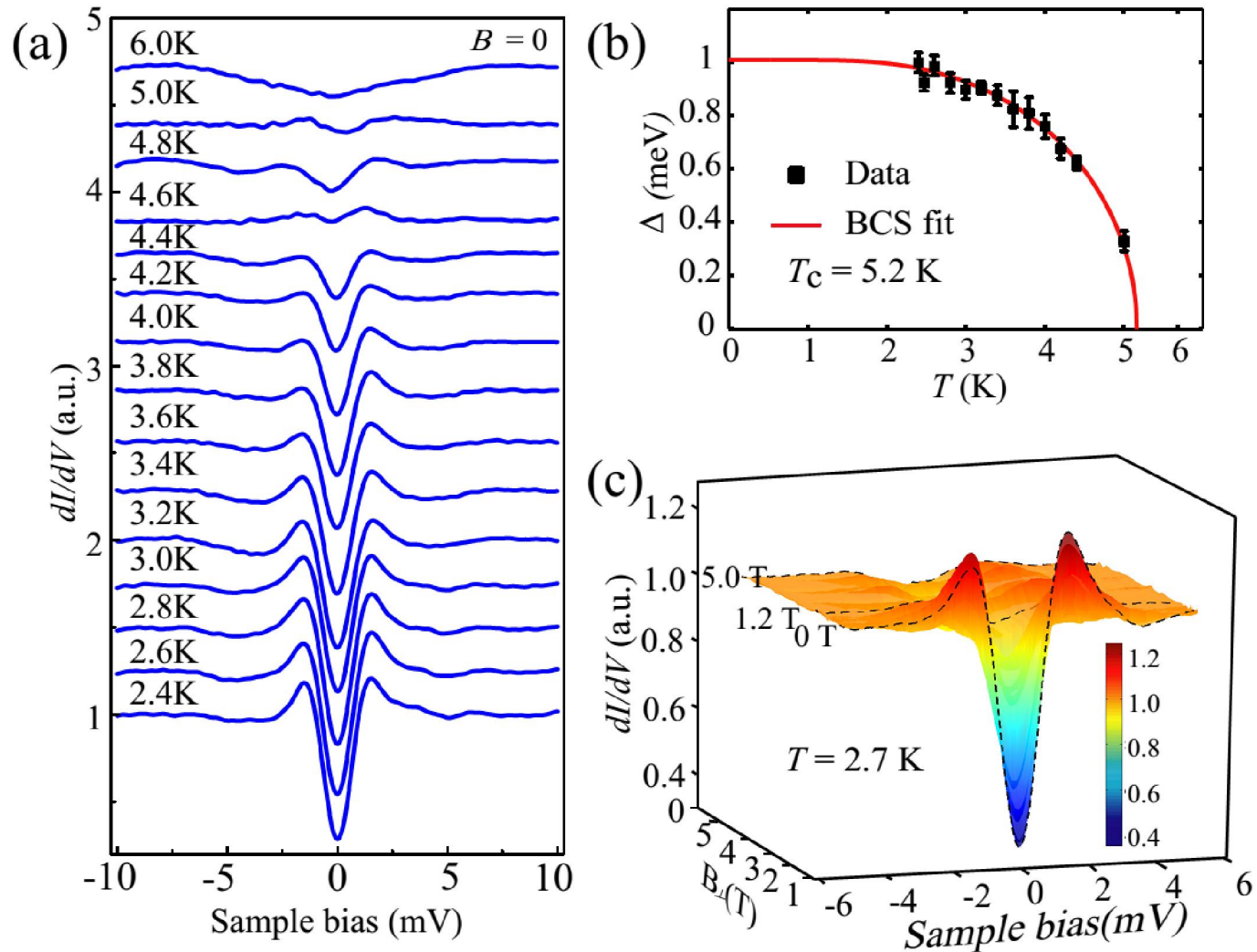
The thickness of the Ga film is **0.552 nm**.

The hexagonal structure and lattice constant ( $a=b=0.318$  nm and  $c = 0.276$  nm)

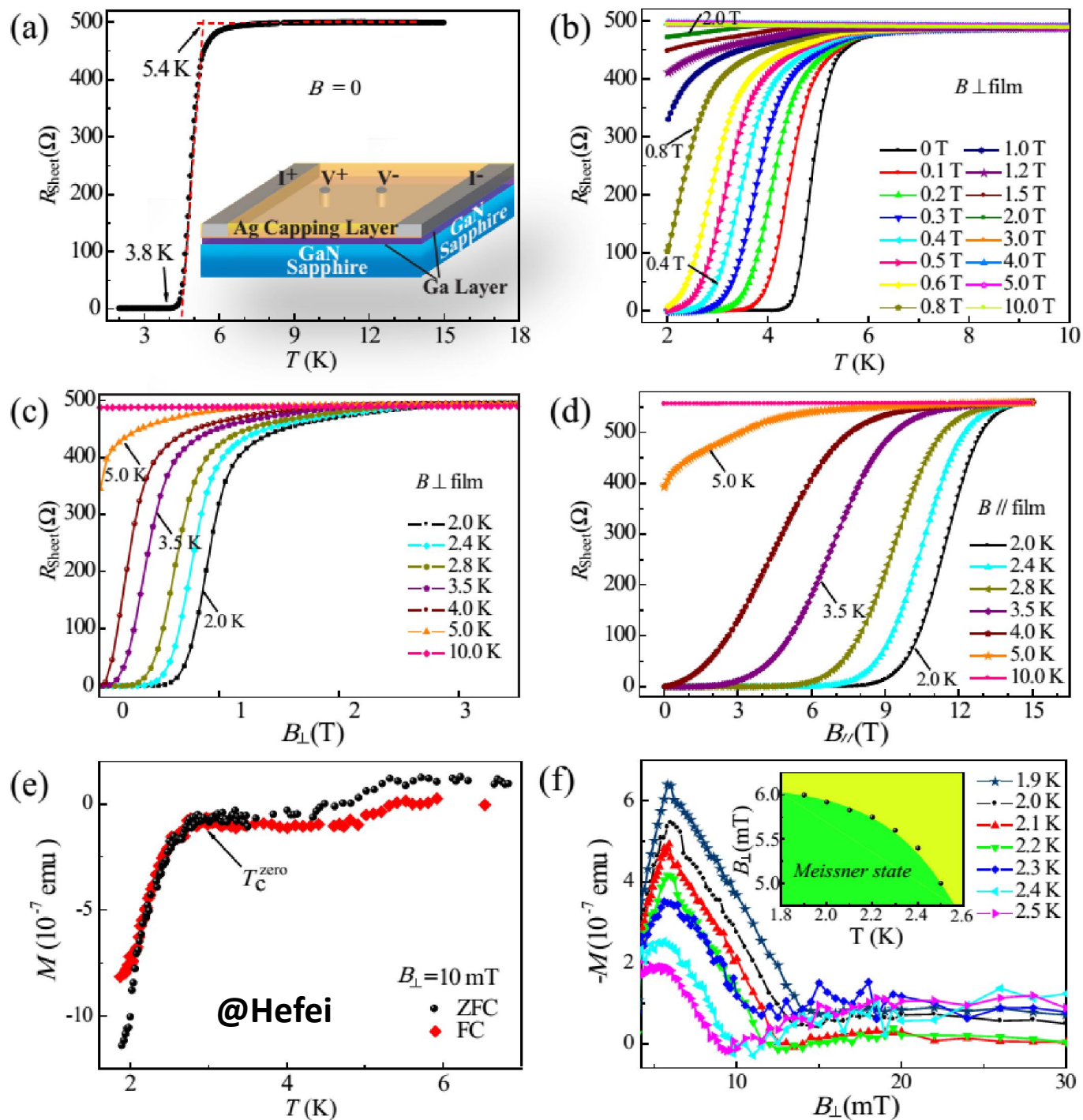


**Graphene and Silicene like Structure!?**

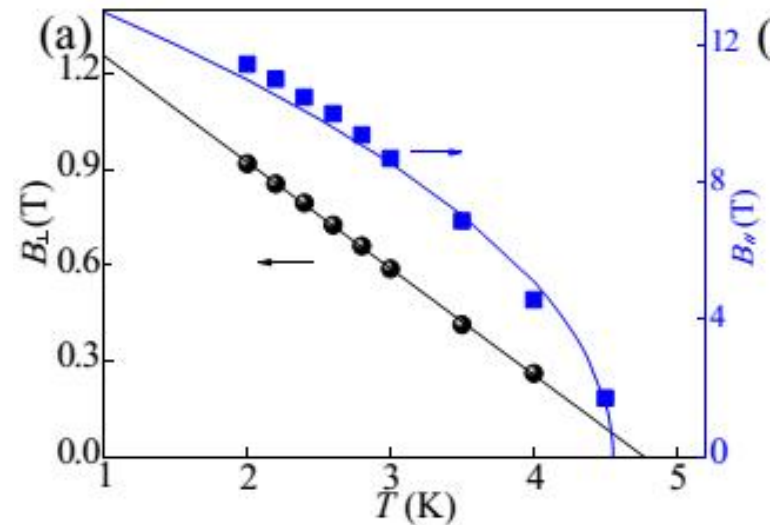
# The superconductivity of two-atom layer Ga film on GaN(0001) detected by *in situ* STM



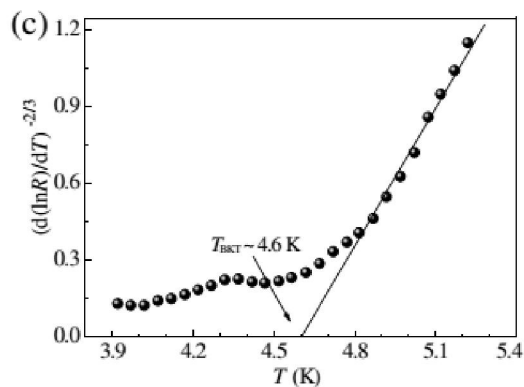
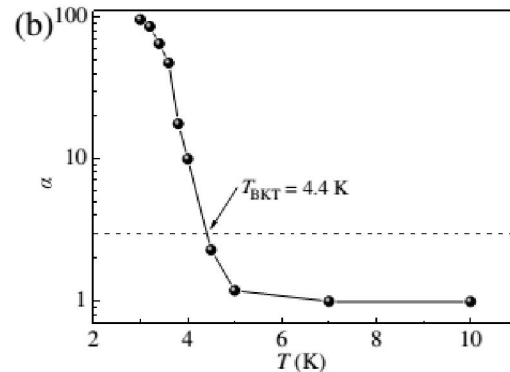
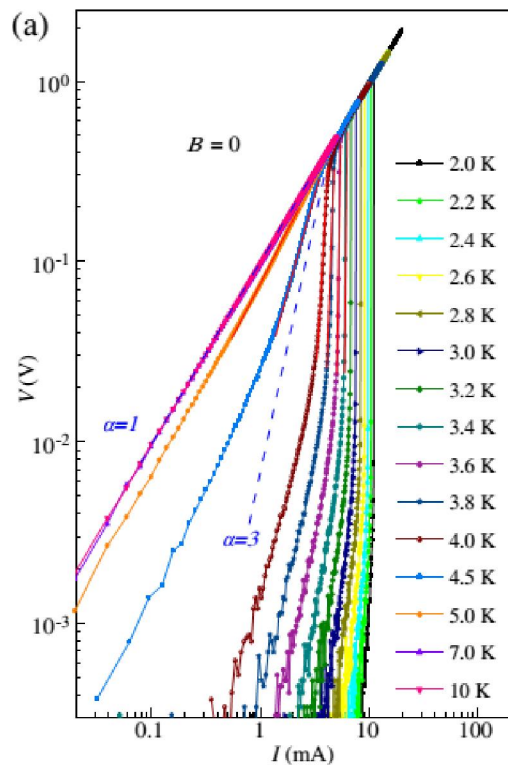
The superconductivity of two-atom layer Ga film on GaN(0001) detected by *ex situ* transport and magnetization measurements.



# Evidences for “ideal” 2D superconductivity:



We observed typical critical field behavior for 2D superconductor.



BKT-like behavior

**Therefore, a new superconducting phase in 2D limit is discovered.**

**Two-atom layer Ga on GaN vs. stable bulk  $\alpha$  phase Ga:**

- 1.  $T_c$ : 5.4 K vs. 1.08 K**
- 2.  $H_c$ : 3.26 T vs. 58.3 Oe**
- 3. Hexagonal vs. orthorhombic (completely different lattice constant)**

*Physical Review Letters 114, 107003 (2015) (Editors' Suggestion)*

# Summary

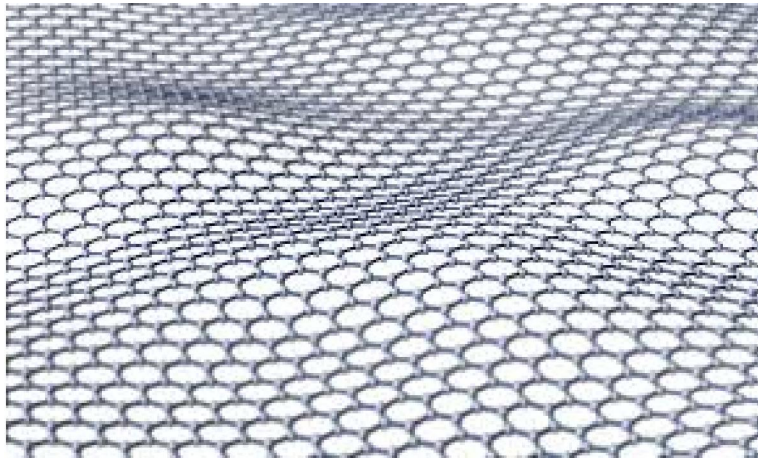
1. By *in situ* STM/STS and *ex situ* transport and magnetization measurements, we discover a new 2D superconducting phase with a transition temperature up to 5.4 K in 2 ML (0.552nm) crystalline Ga films grown on wide band-gap semiconductor GaN.
2. It is the first conventional crystalline superconductor in 2D limit showing **T<sub>c</sub> enhancement and *ex situ* superconductivity**. The observed superconductivity in atomic-scale thin films with relatively high  $T_c$  and  $H_c$  demonstrates the feasibility in developing dissipationless quantum electronic devices based on wide band-gap semiconductors.
3. Our result demonstrates a pathway for exploring atomic-scale 2D superconductors by surface and interface engineering in a broad range of **metal-semiconductor heterostructures**, which benefit from present semiconductor technology and ultrathin film fabrication technique.

*Physical Review Letters 114, 107003 (2015) (Editors' Suggestion)*

# Perspective

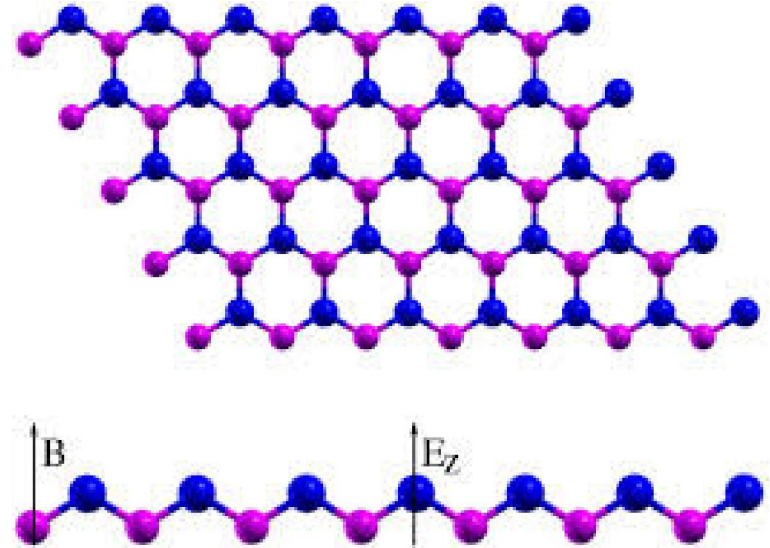
The two-atom Ga layer shows graphene and silicene like structure!

## Graphene



[www.wearable-technologies.com](http://www.wearable-technologies.com)

## Silicene



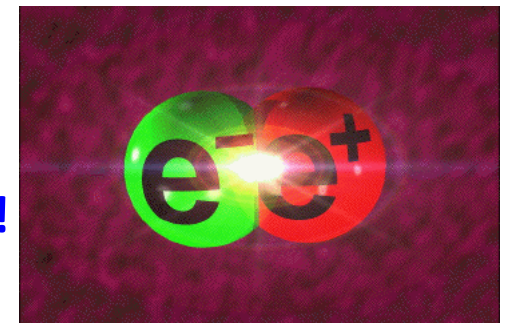
[www.nature.com](http://www.nature.com)

Does two-atom layer Ga show topological property?

Can it be a candidate of topological superconductors?

More experiments, calculations, and theories are necessary!

镓烯? "Made in China"



Majorana Fermion





## **Part III: Potential to topological superconductivity in 3D Dirac semimetal**

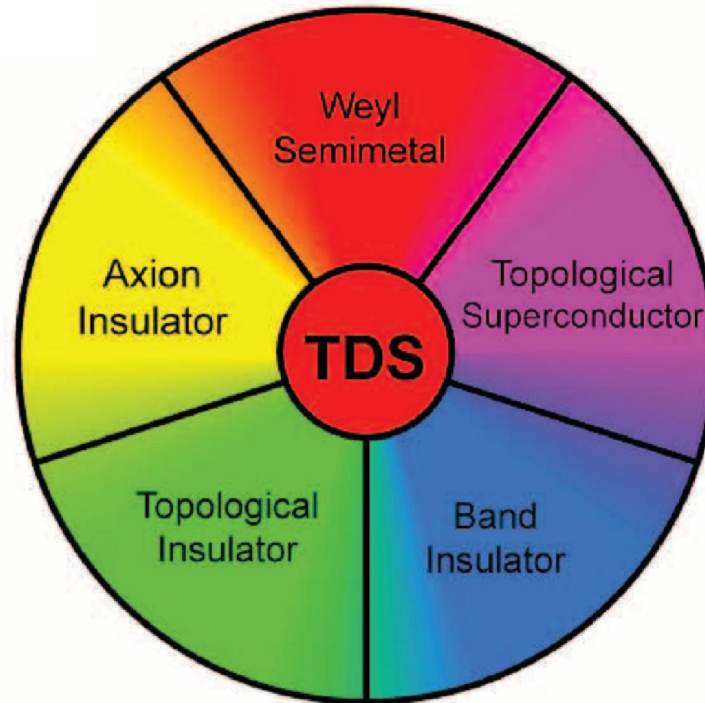
*[arXiv:1412.0330](#)*

*[arXiv:1501.00418](#)*

# Background: 3D Topological Dirac Semimetal

“3D graphene”

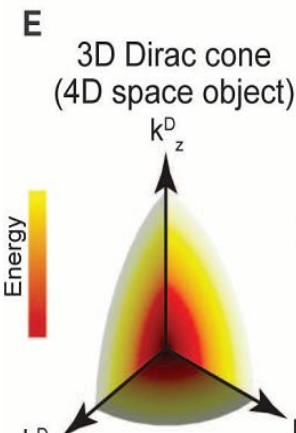
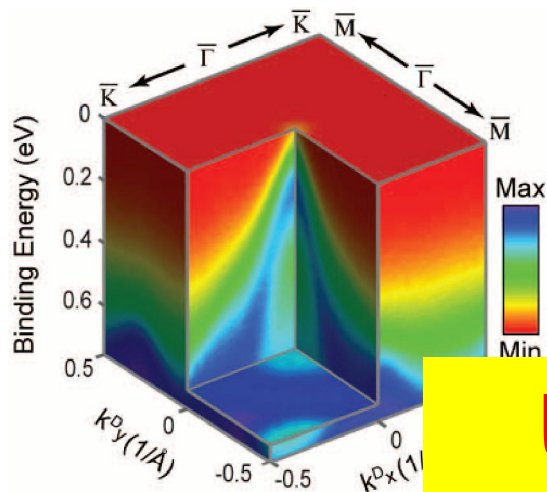
**Rich Novel States**



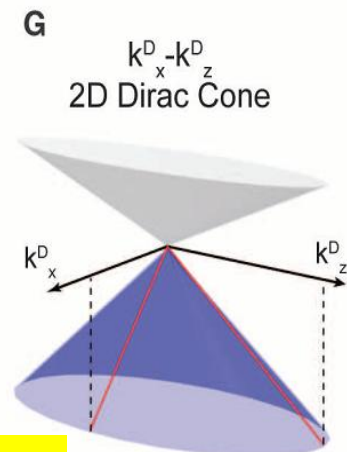
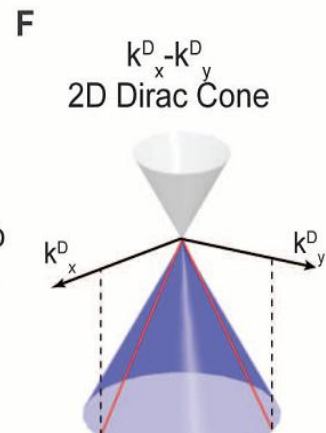
Z. K. Liu et al, Science 343, 864 (2014)

# 3D Topological Dirac Semimetal

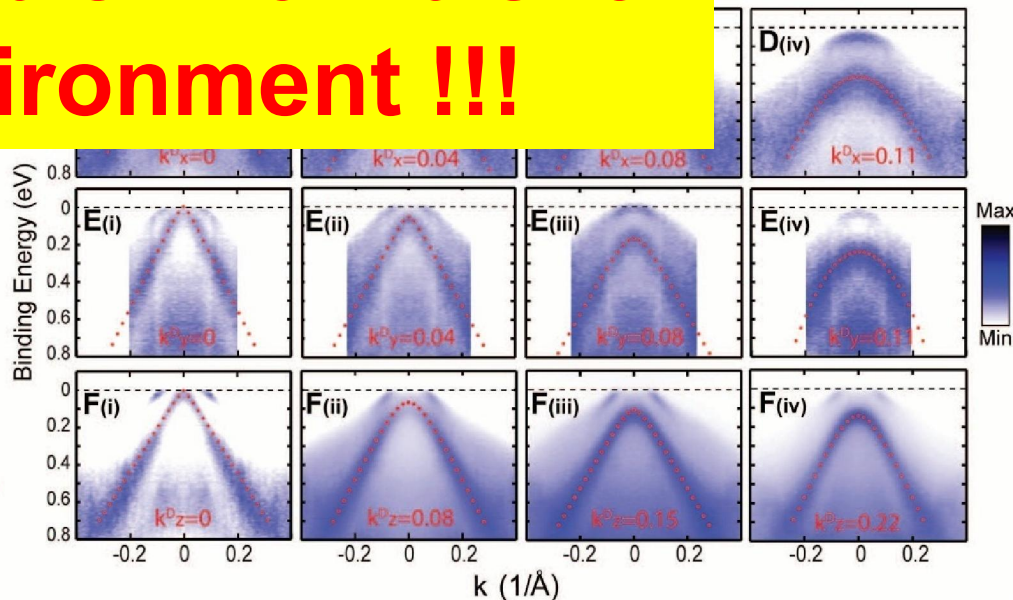
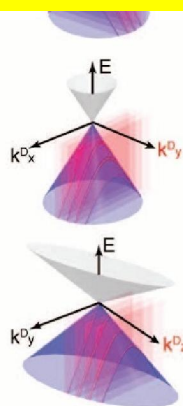
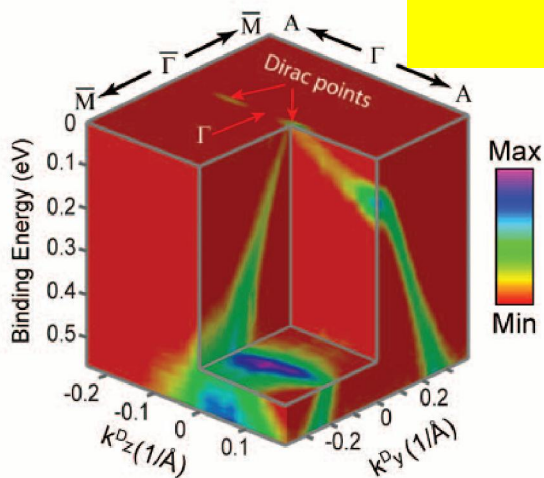
Na<sub>3</sub>Bi



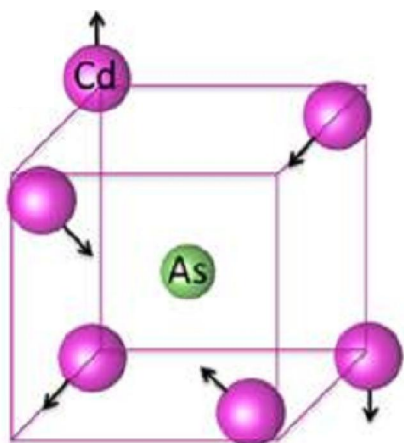
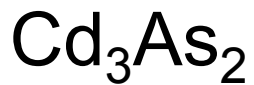
Projection to  
3D space



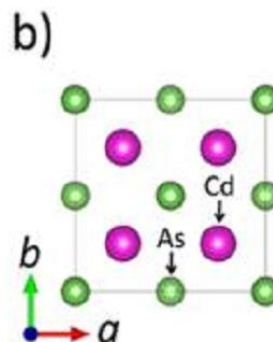
**Unstable in ambient environment !!!**



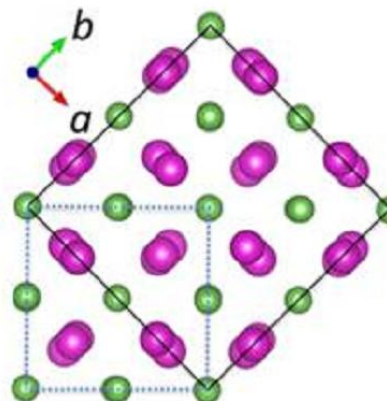
# 3D Topological Dirac Semimetal



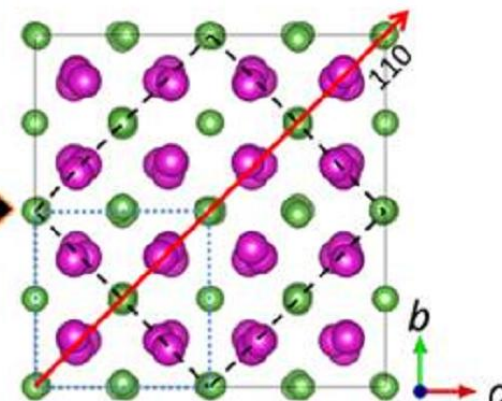
Fm-3m HT



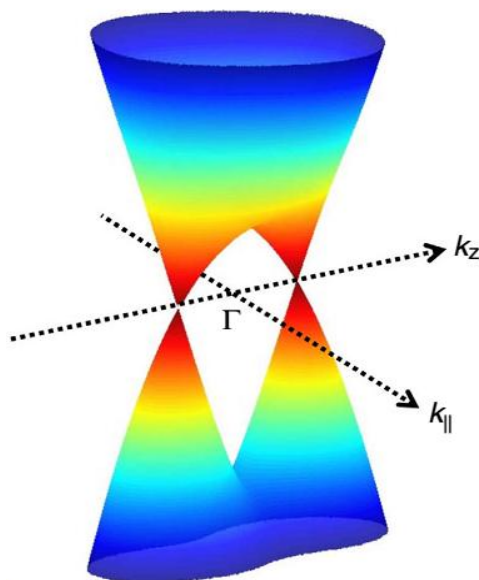
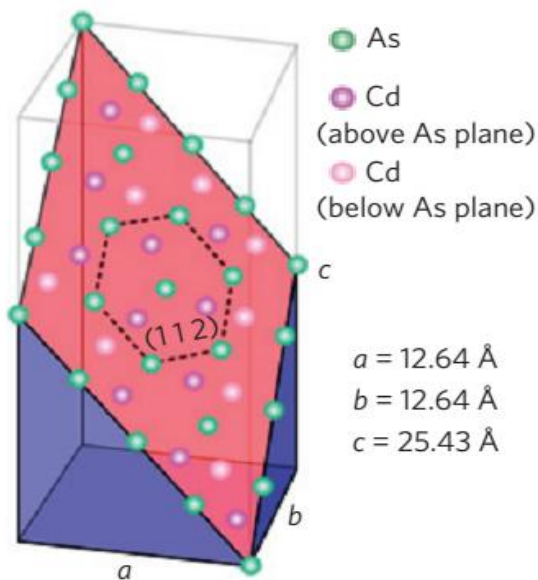
P42/nmc IT



I4<sub>1</sub>/acd LT



3D Dirac semimetal  
( $\text{Cd}_3\text{As}_2$ ,  $\text{Na}_3\text{Bi}$ )



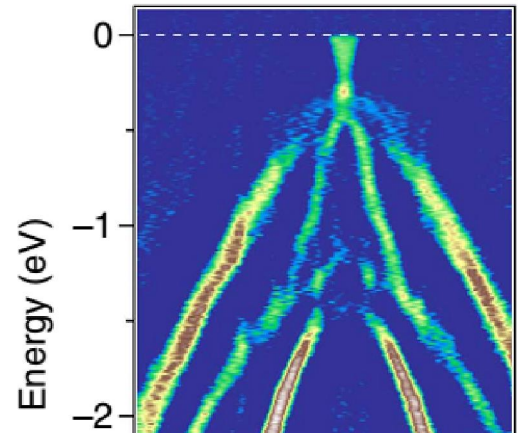
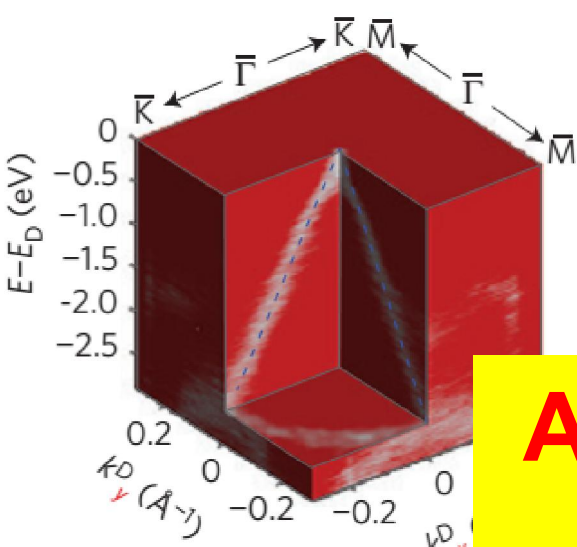
M. N. Ali, et al, Inorg. Chem. 53, 4062 (2014)

S. Jeon, et al, Nat. Mater. 13, 851 (2014)

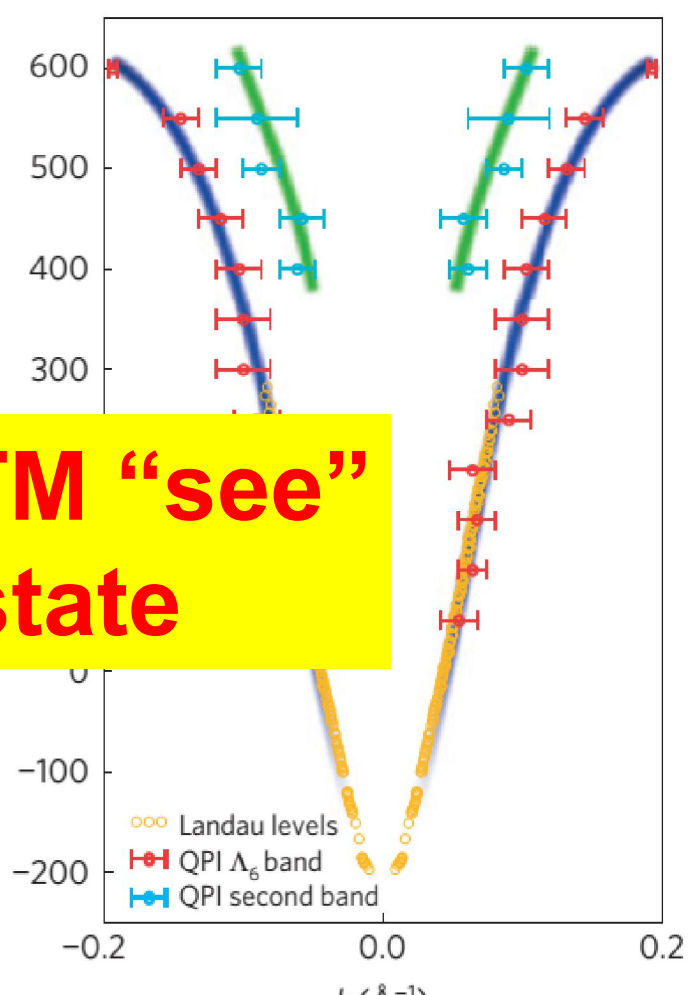
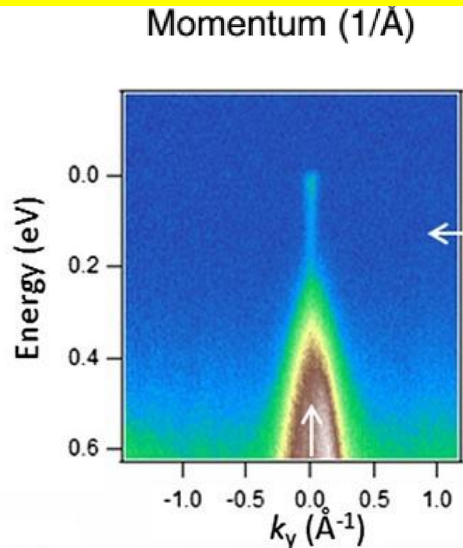
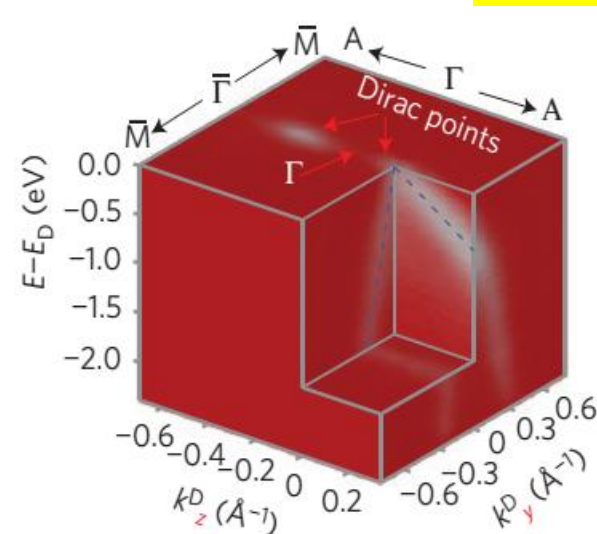
M. Neupane, et al, Nat. Commum 5, 3786 (2014)

# 3D Topological Dirac Semimetal

$\text{Cd}_3\text{As}_2$



**ARPES and STM “see” the Dirac state**



Z. K. Liu, et al, Nat. Mater. 7, 677 (2014)  
 S. Jeon, et al, Nat. Mater. 13, 851 (2014)  
 M. Neupane, et al, Nat. Commum 5, 3786 (2014), PRL 113,027603 (2014)

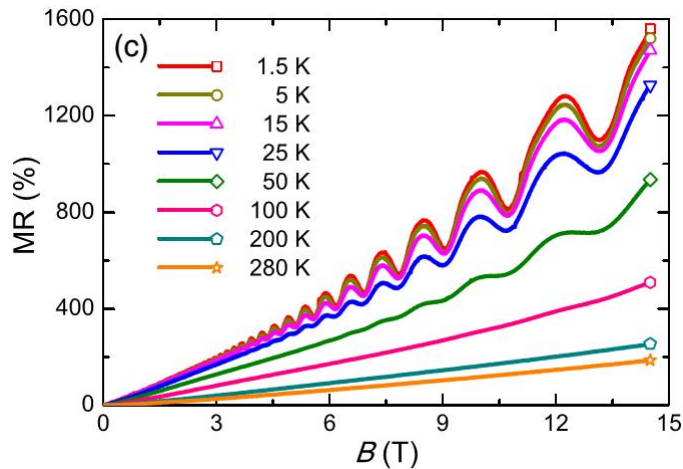
# 3D Topological Dirac Semimetal



**Table 1 | Parameters of the seven samples investigated.**

Sample	$\rho_1$ (n $\Omega$ cm)	$\gamma$	RRR	$\mu_1$ (cm <sup>2</sup> V <sup>-1</sup> s <sup>-1</sup> )	MR (9 T)	$n_H$ (9 T) (10 <sup>18</sup> cm <sup>-3</sup> )
A1	32	32.7	781	$\sim 3 \times 10^6$ *	582	9.1
A4	14,600	2.72	21.4	$40 \times 10^3$	34.5	4.4
A5	21	18.7	4,100	$8.7 \times 10^6$	1,336	7.4
A6	4,000	22.6	32.2	$320 \times 10^3$	112	12.0
A8	110	12.8	118	$4.0 \times 10^6$	404	13.3
B1	46,500	-	5.37	$\sim 10 \times 10^3$ *	36.9	-
B7	32,200	-	7.26	$\sim 20 \times 10^3$ *	62.2	15

$\rho_1$  is the resistivity along  $\hat{x}$  at 5 K. The anisotropy  $\gamma$  is  $\rho_2/\rho_1$  at 5 K ( $\gamma$  is undefined in B1 and B7). RRR is the ratio  $\rho_1(300)/\rho_1(5)$ . The mobilities are determined from  $\sigma_{xy}$  and  $\gamma$ , except in A1, B1 and B7 (\*) where they are estimated from the residual resistivity. MR is the ratio  $\rho_{xx}(9\text{T})/\rho_{xx}(0)$  at 5 K. The Hall density  $n_H$  (9 T) equals  $B/e\rho_{yx}$  measured at 9 T (all n-type).



**Ultrahigh mobility**

**LMR**

**SdH Oscillations**

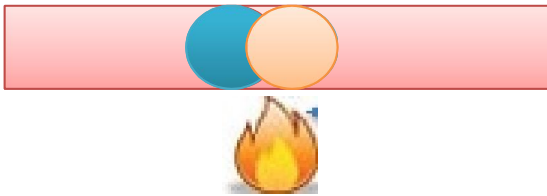
Nat. Mater. 14, 280 (2015)

Phys. Rev. Lett. 113, 246402 (2014)

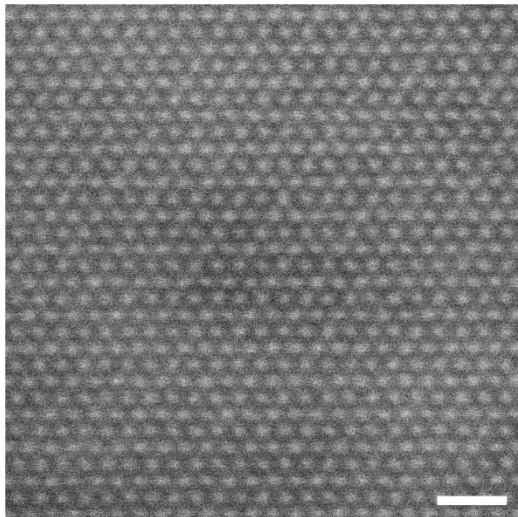
# Sample Growth

- Flux crystal growth

Cd:As=85:15



Heat up to 825°C



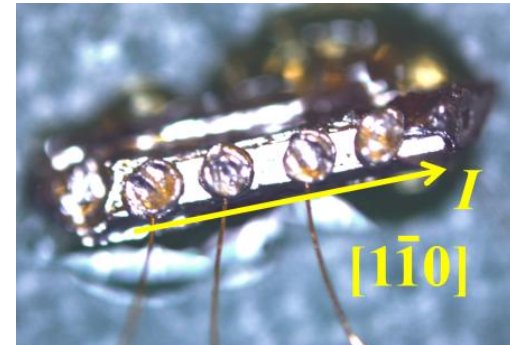
T = 825°C  
Keep 48 hours

Rate  
6°C/h

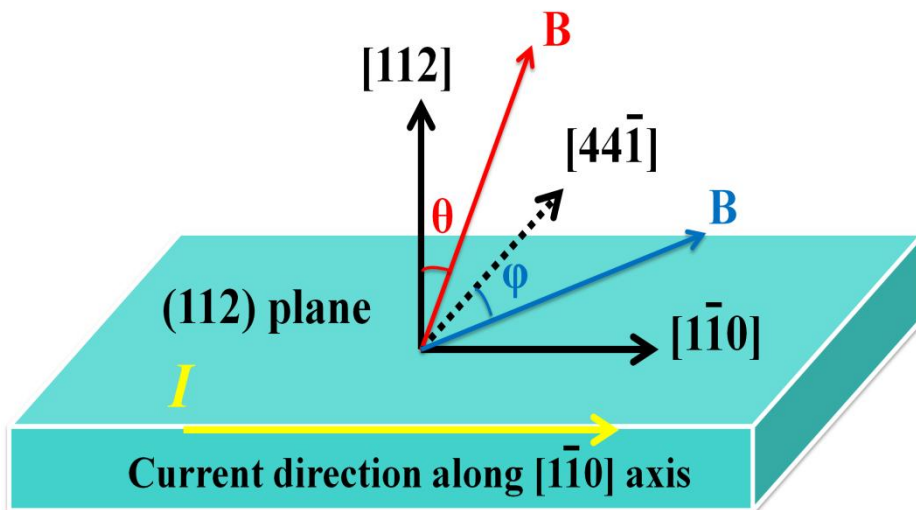
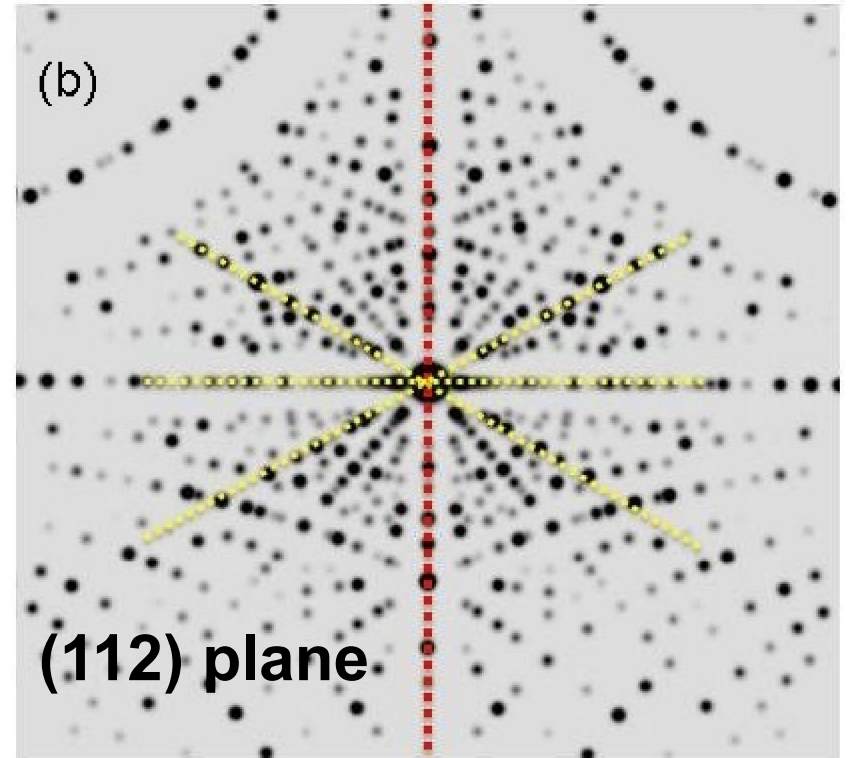
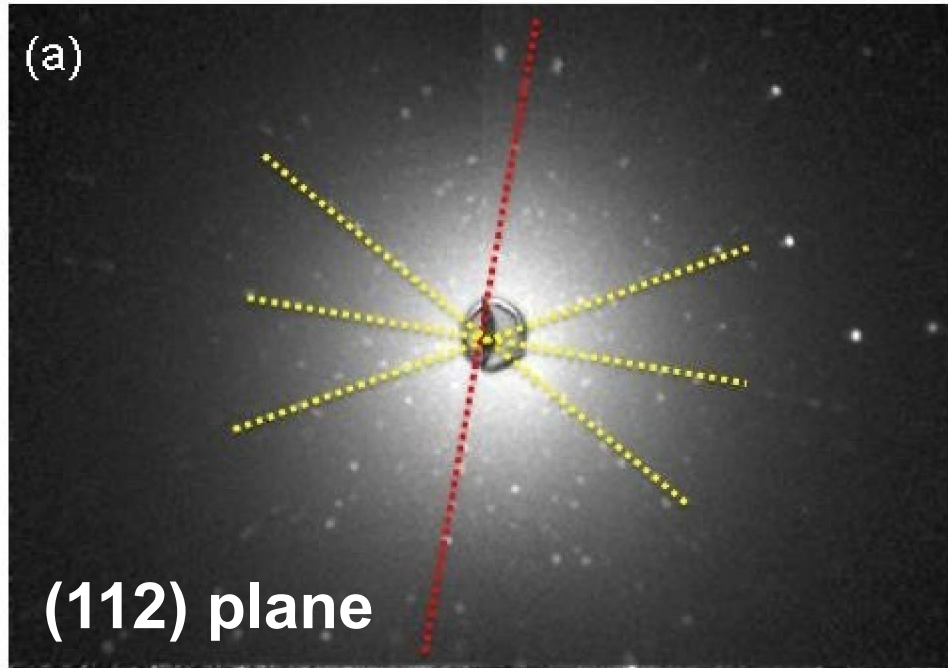
Cool down  
to 425°C

Decant the  
remaining liquid

Cd<sub>3</sub>As<sub>2</sub>  
Single Crystal



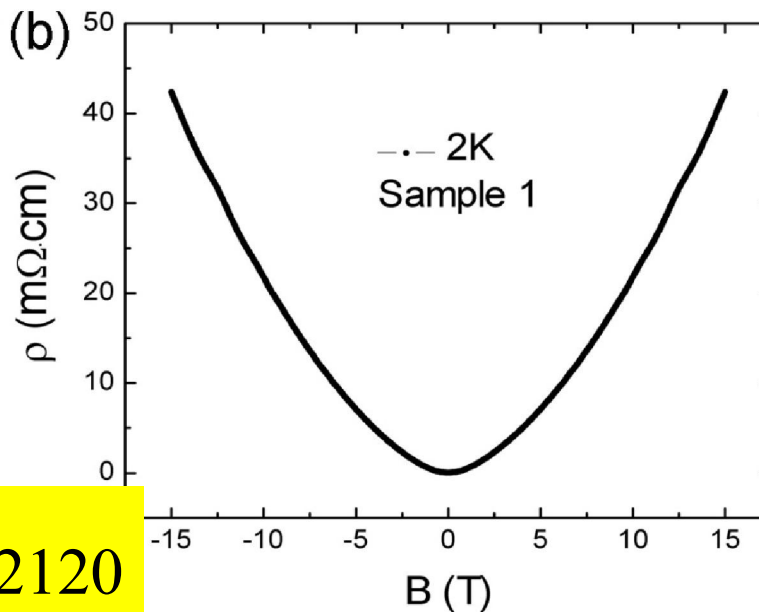
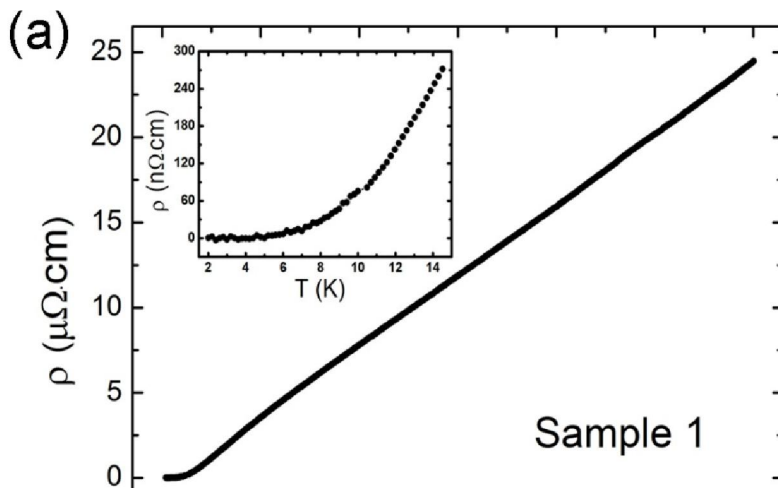
# Laue Image



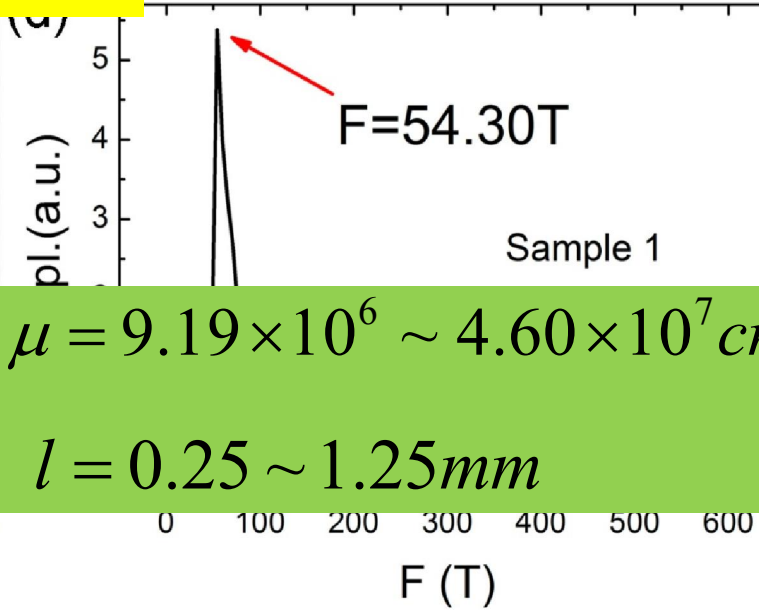
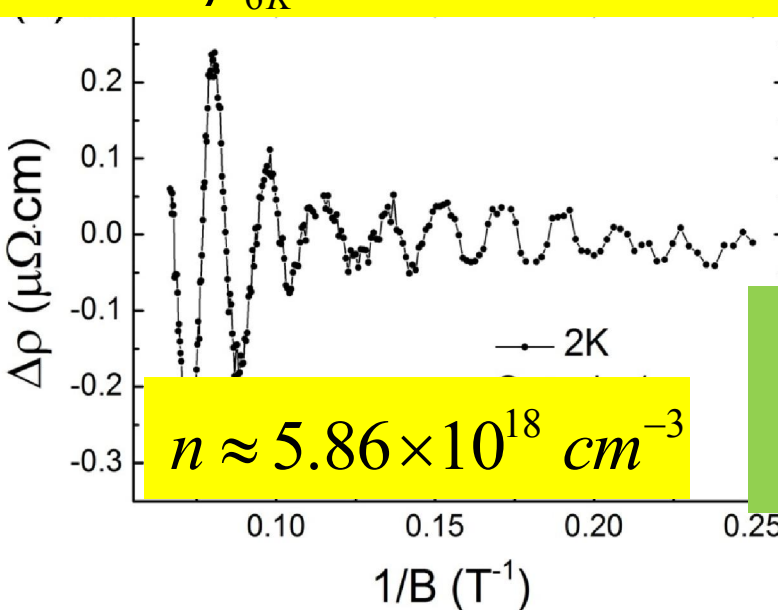
Transport Sketch map



# Ultrahigh Mobility



$$RRR = \frac{\rho_{300K}}{\rho_{6K}} = \frac{24.6\ \mu\Omega\cdot\text{cm}}{11.6\ \text{n}\Omega\cdot\text{cm}} = 2120$$

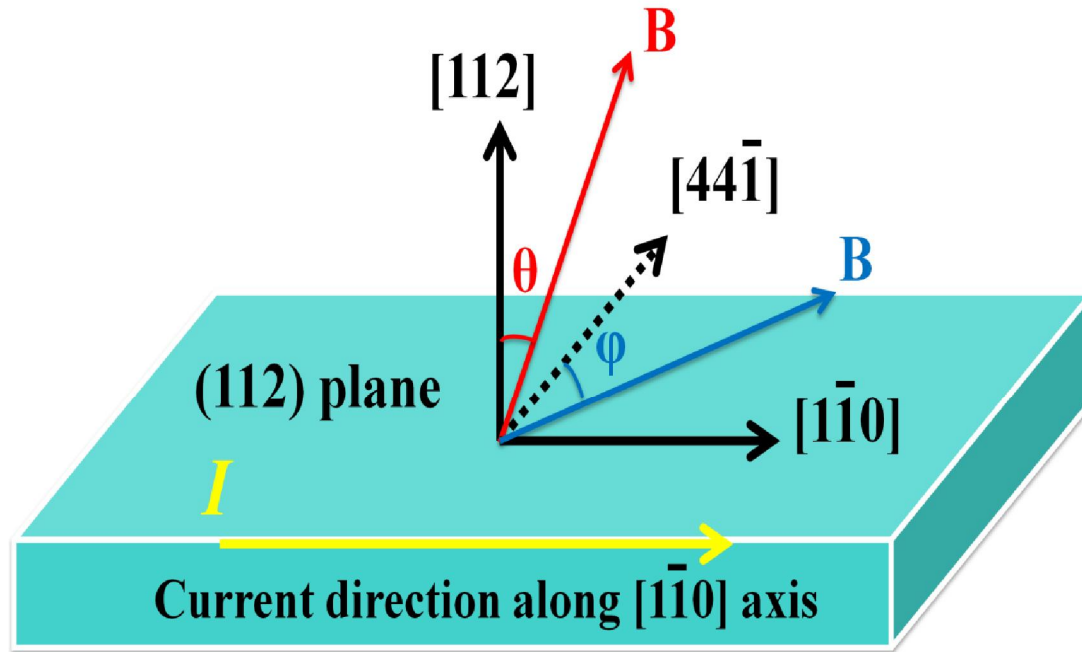


$$n \approx 5.86 \times 10^{18}\ \text{cm}^{-3}$$

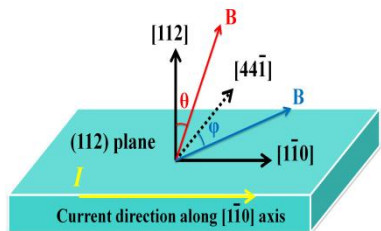
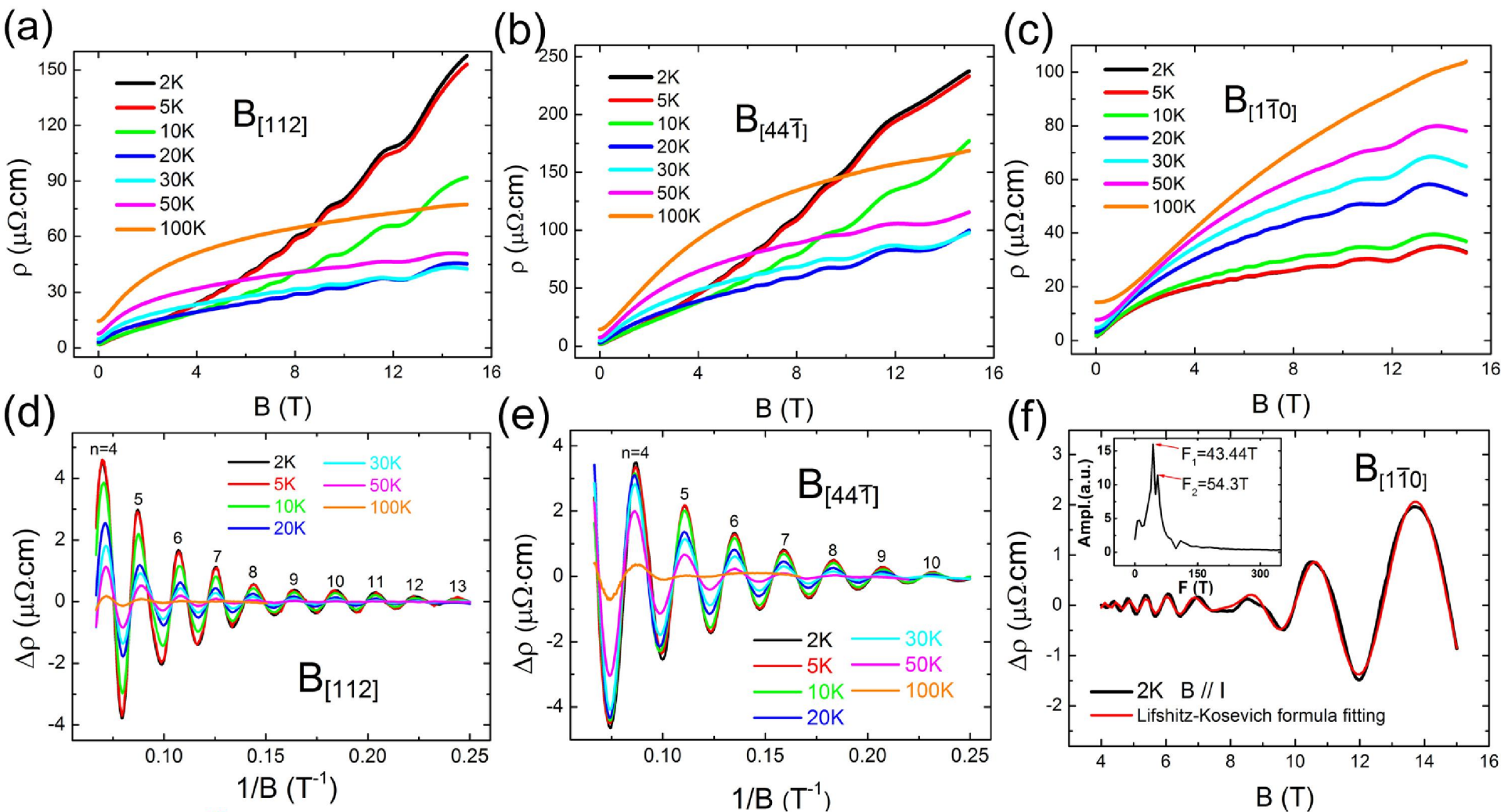
$$\mu = 9.19 \times 10^6 \sim 4.60 \times 10^7\ \text{cm}^2 / \text{Vs}$$

$$l = 0.25 \sim 1.25\ \text{mm}$$

# 3D Anisotropic Fermi Surface

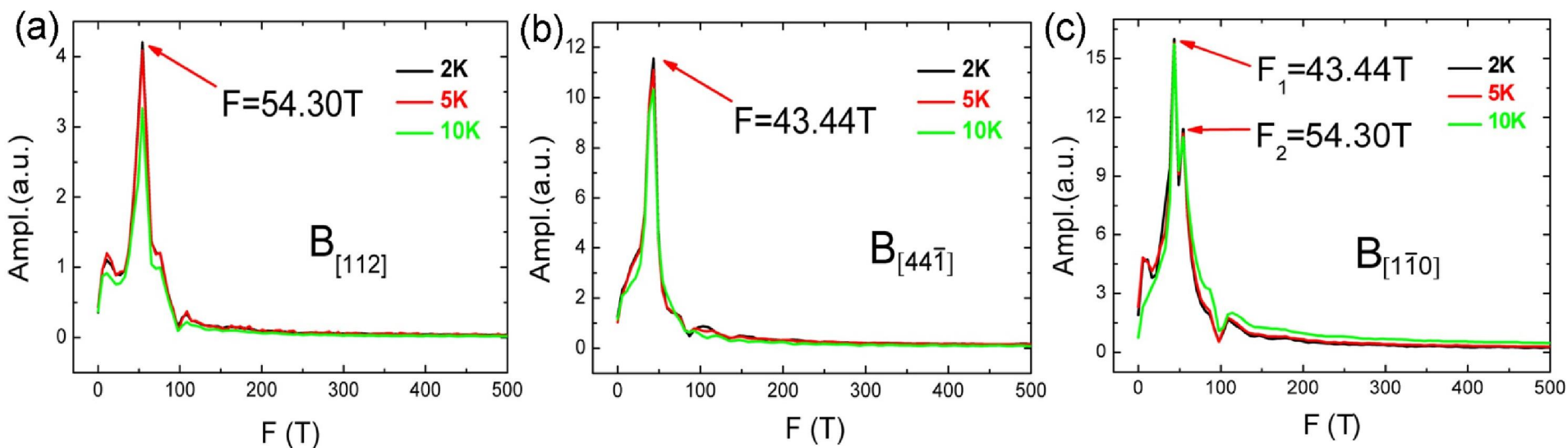


# 3D Anisotropic Fermi Surface



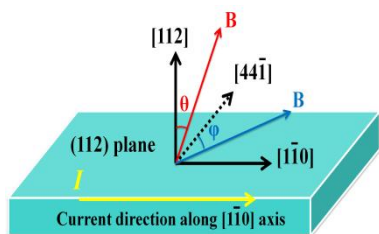
**[112] and  $[44\bar{1}]$  single period SdHO**  
 **$[1\bar{1}0]$  two periods SdHO**

# 3D Anisotropic Fermi Surface

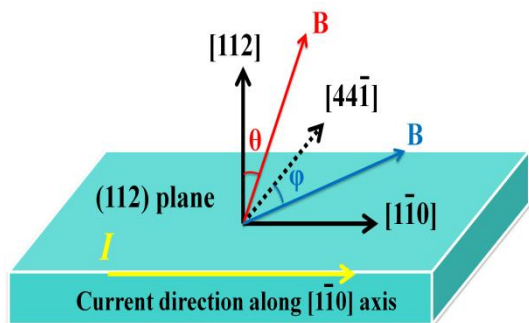


## Anisotropic Fermi surface

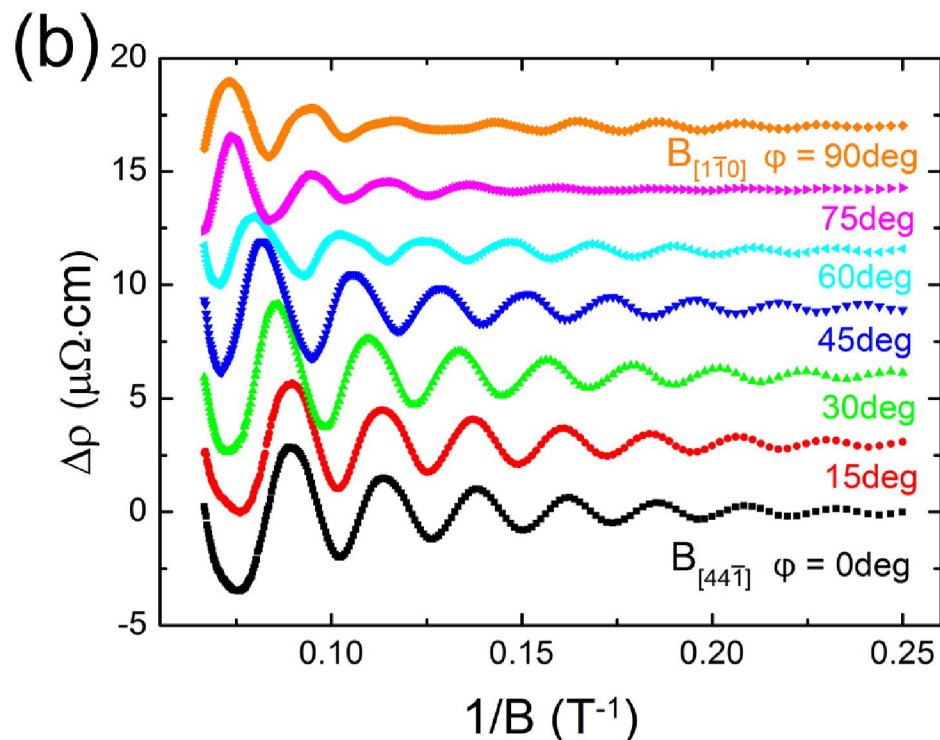
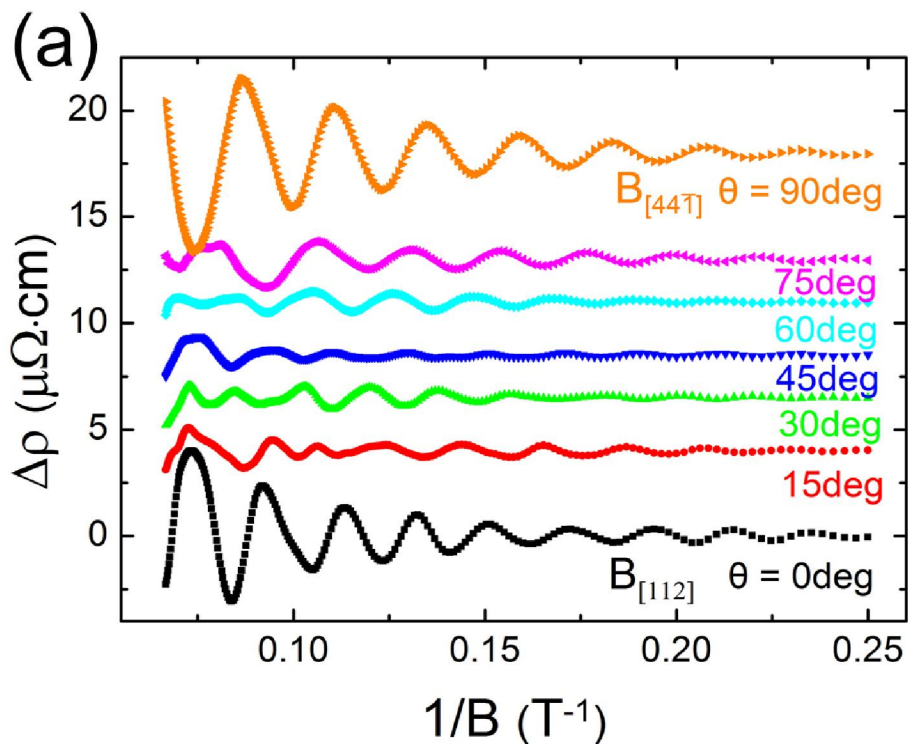
**[112] and [44 $\bar{1}$ ] single period SdHO**  
**[1 $\bar{1}$ 0] two periods SdHO**



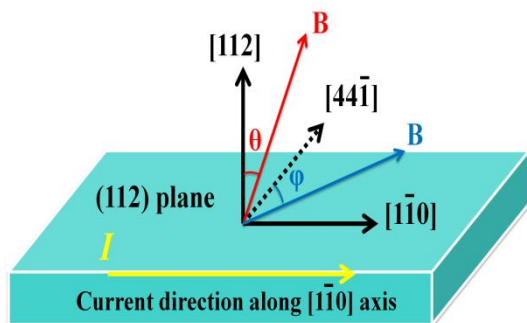
# 3D Anisotropic Fermi Surface



**[112] and  $[44\bar{1}]$  single period SdHO**  
 **$[\bar{1}10]$  two periods SdHO**  
**Anisotropic Fermi surface**



# 3D Anisotropic Fermi Surface



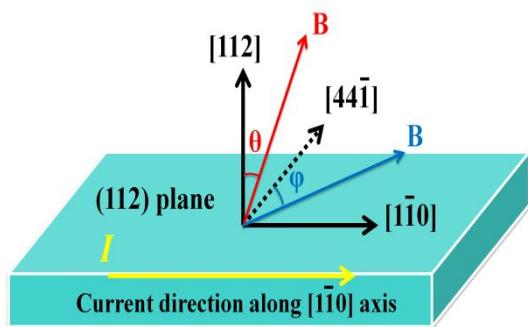
**[112] and  $[44\bar{1}]$  single period SdHO**  
 **$[1\bar{1}0]$  two periods SdHO**  
**Anisotropic Fermi surface**

TABLE I: FFT analysis of SdH oscillations in various magnetic field directions.

Rotation angle	0 deg	15 deg	30 deg	45 deg	60 deg	75 deg	90 deg
$B_{[112]}$ rotate	54.30 T	43.44 T	48.87 T	54.30 T	48.87 T	43.44 T	43.44 T
to $B_{[44\bar{1}]}$	–	54.3 T	59.73 T	–	–	–	–
$B_{[44\bar{1}]}$ rotate	43.44 T	43.44 T	43.44 T	43.44 T	43.44 T	48.87 T	43.44 T
to $B_{[1\bar{1}0]}$	–	–	–	–	48.87 T	43.44 T	54.30 T

**When changing the magnetic field angle  $\theta$  and  $\phi$ ,  
two periods oscillations also present**

# 3D Anisotropic Fermi Surface

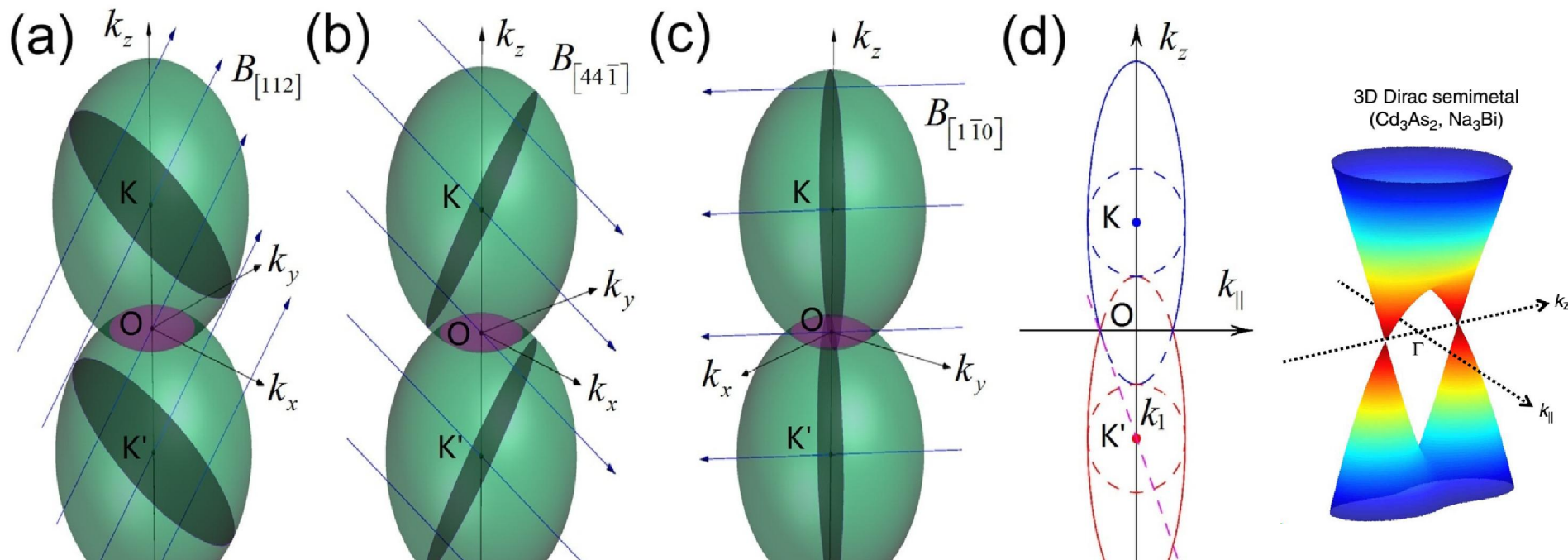


**[112] and  $[44\bar{1}]$  single period SdHO**

**$[1\bar{1}0]$  two periods SdHO**

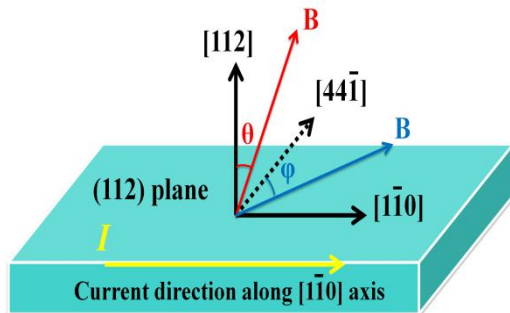
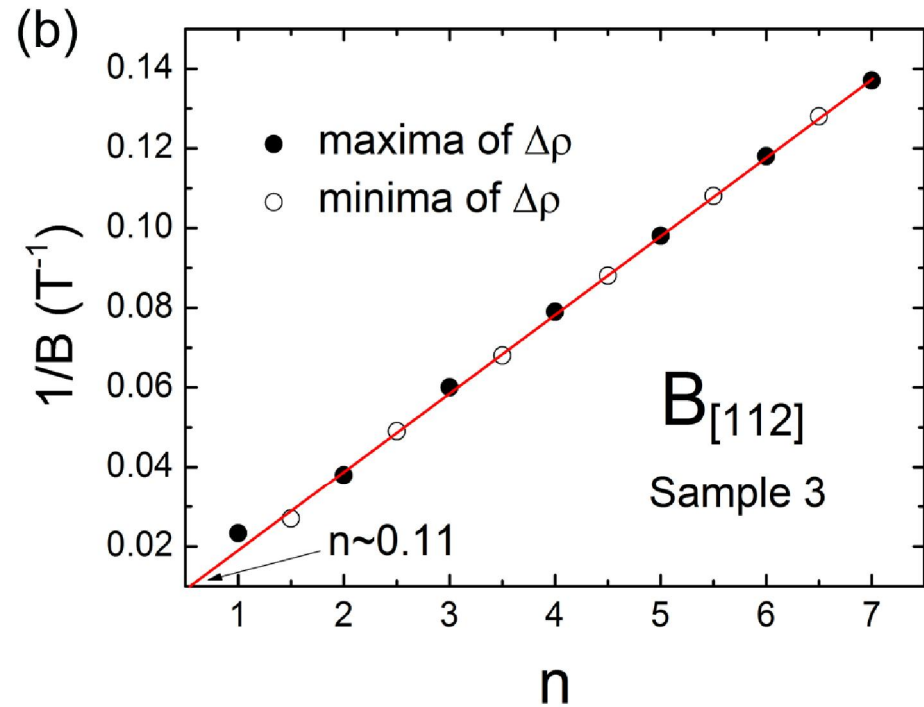
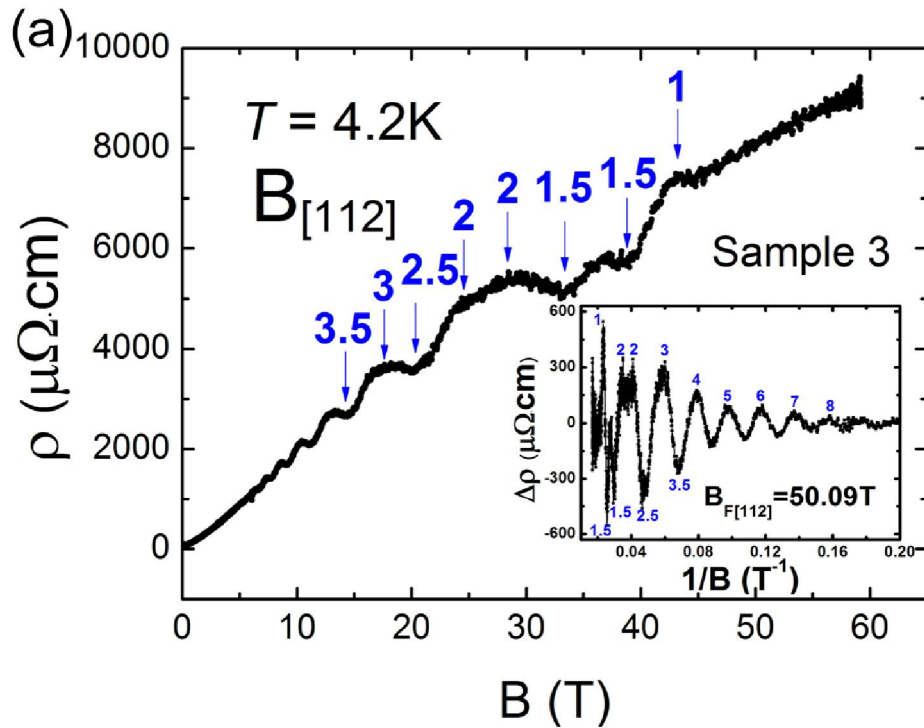
**Anisotropic Fermi surface**

**At certain angle: two periods SdHO**



Two nested ellipsoid Fermi surface beyond the Lifshitz point

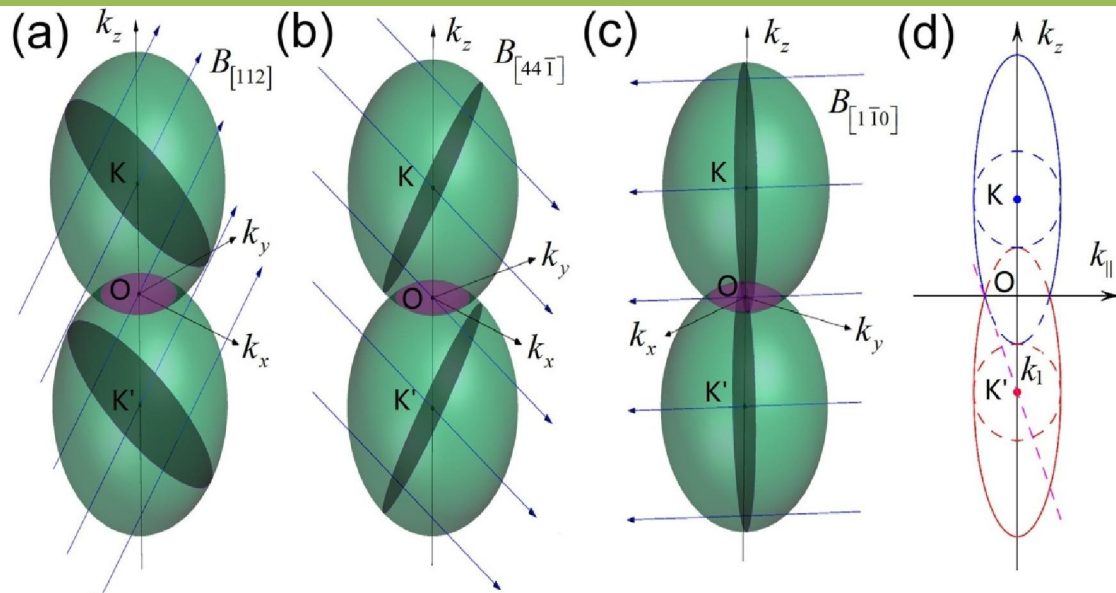
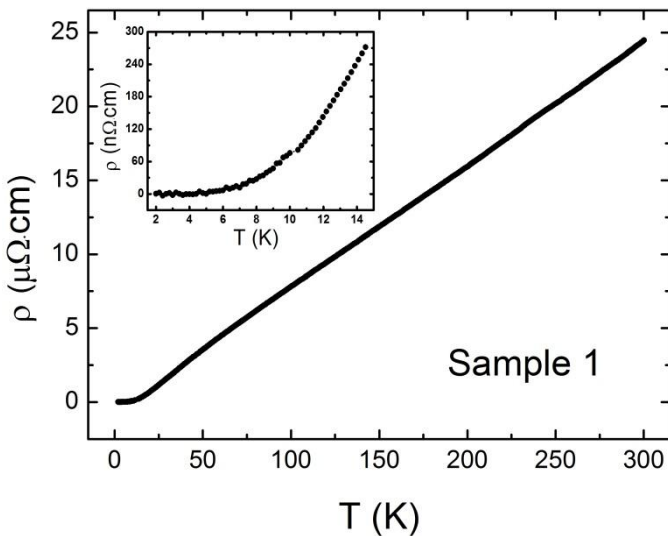
# Quantum Limit



- Quantum limit:  $n = 1$
- SdH Oscillation with Zeeman Splitting
- Linear MR behavior
- LL fan deviate from linear fitting: Quantum limit

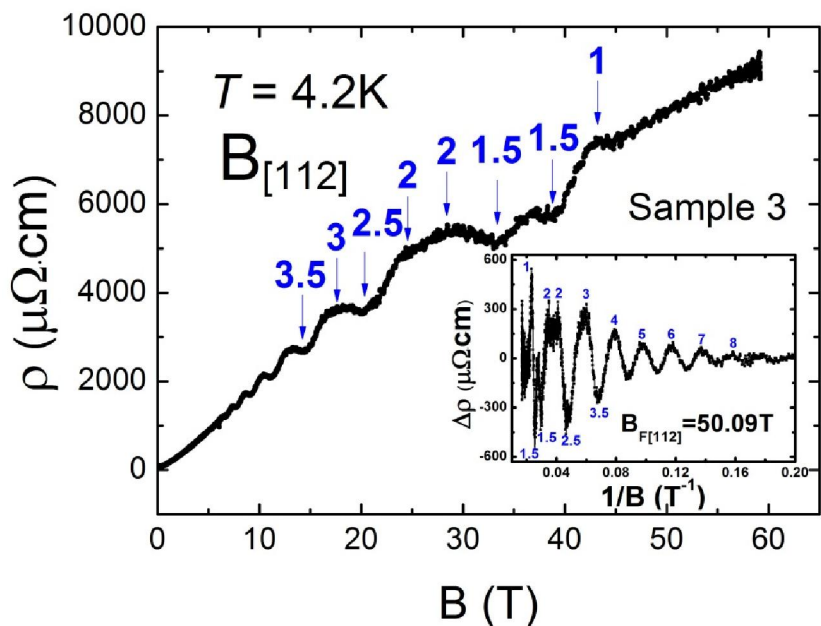


# Transport property – $\text{Cd}_3\text{As}_2$



**Ultrahigh mobility**

**Two nested Anisotropic Fermi surface**



**Quantum Limit**



**Yanfei Zhao**

**Yanfei Zhao et al.** arXiv: 1412.0330

# Observation of superconductivity induced by point contact in 3D Dirac semimetal Cd<sub>3</sub>As<sub>2</sub> crystal

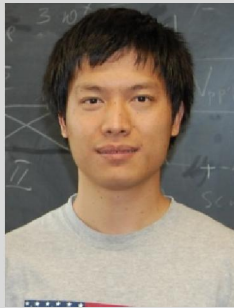
[arXiv:1501.00418](https://arxiv.org/abs/1501.00418)

## Major Collaborators:

### Peking University



Prof. Jian  
Wei



Prof. Xiong-  
Jun Liu



Prof. X. C.  
Xie



Prof. Shuang  
Jia



He Wang



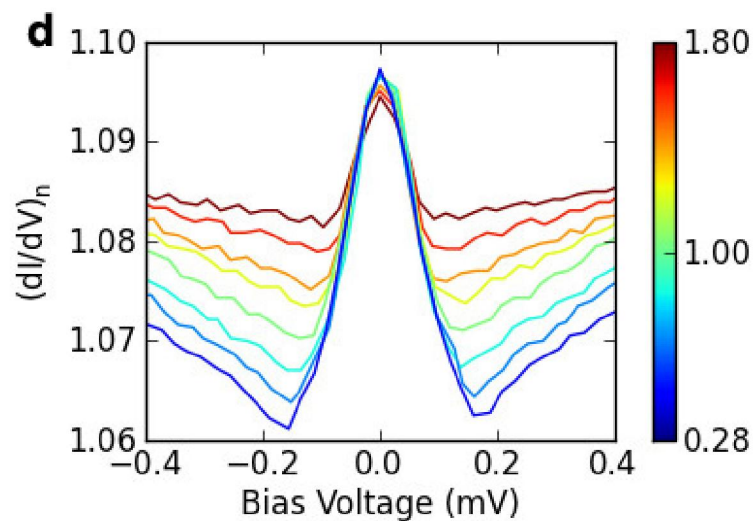
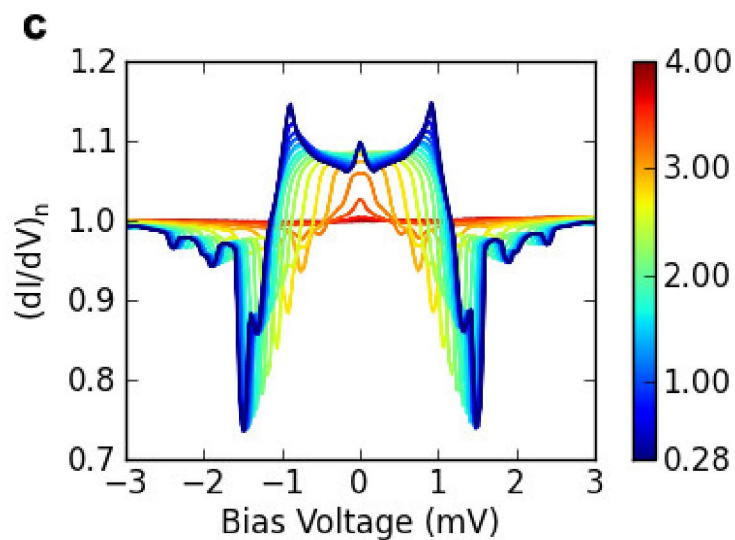
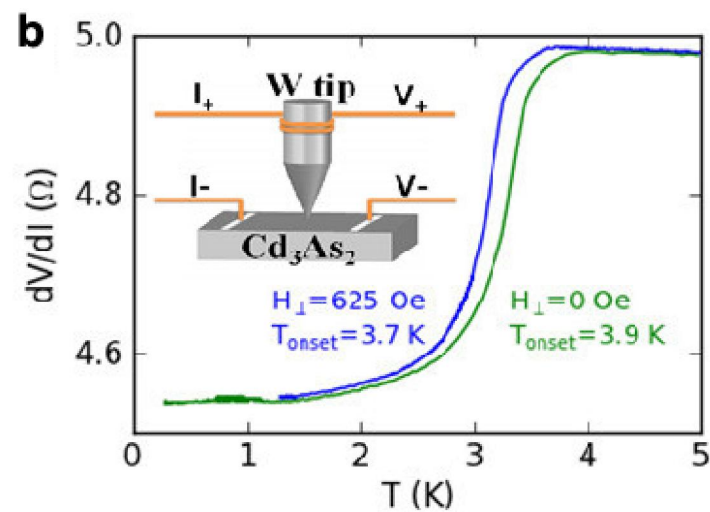
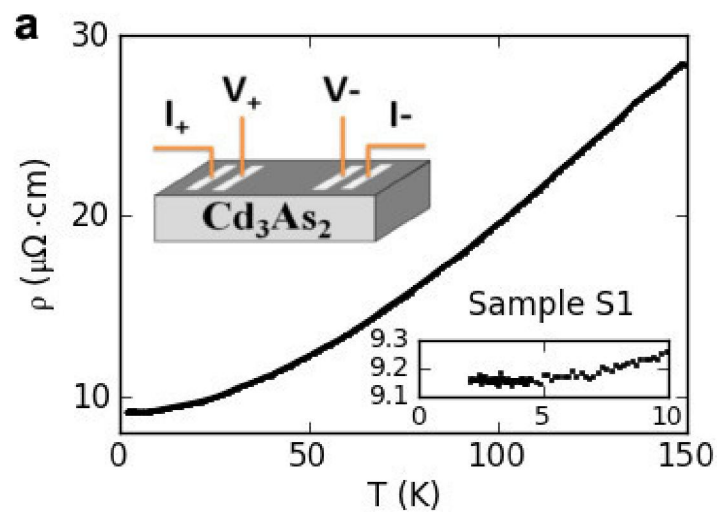
Huichao  
Wang



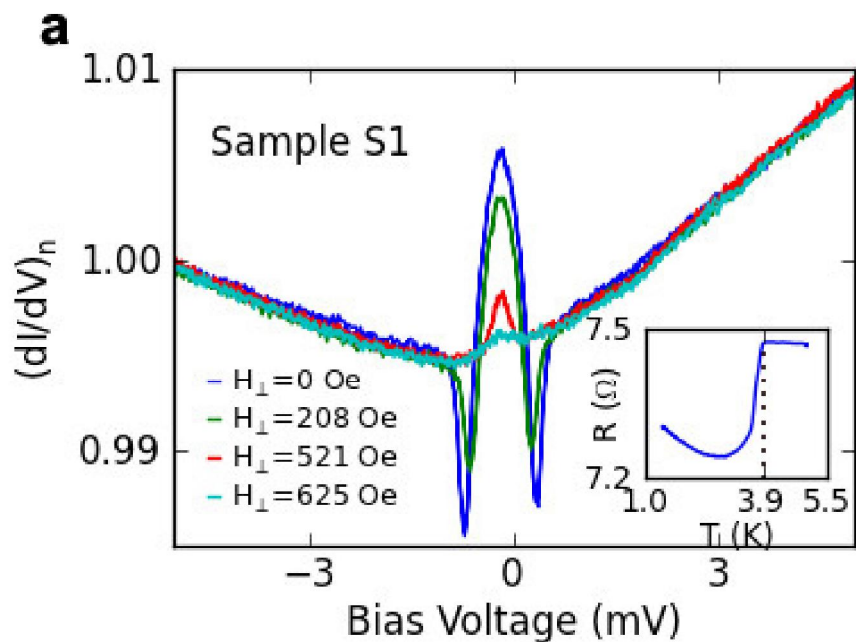
Haiwen  
Liu

**All authors:** He Wang, Huichao Wang, Haiwen Liu, Hong Lu, Wuhao Yang, Shuang Jia, Xiong-Jun Liu, X. C. Xie, Jian Wei, and Jian Wang

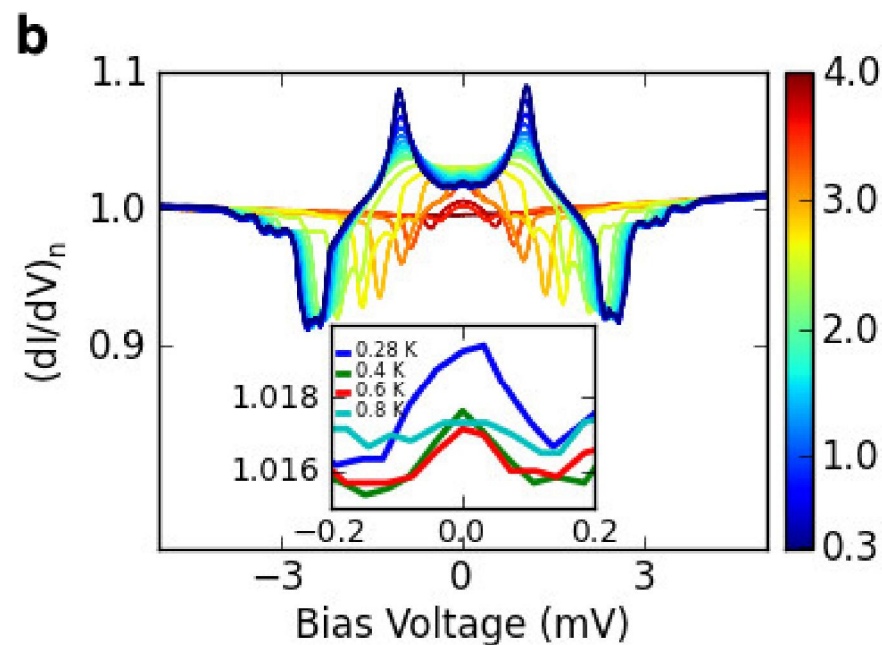
# The data from Sample 1: the observation of superconductivity



The data from Sample 1 on another site:

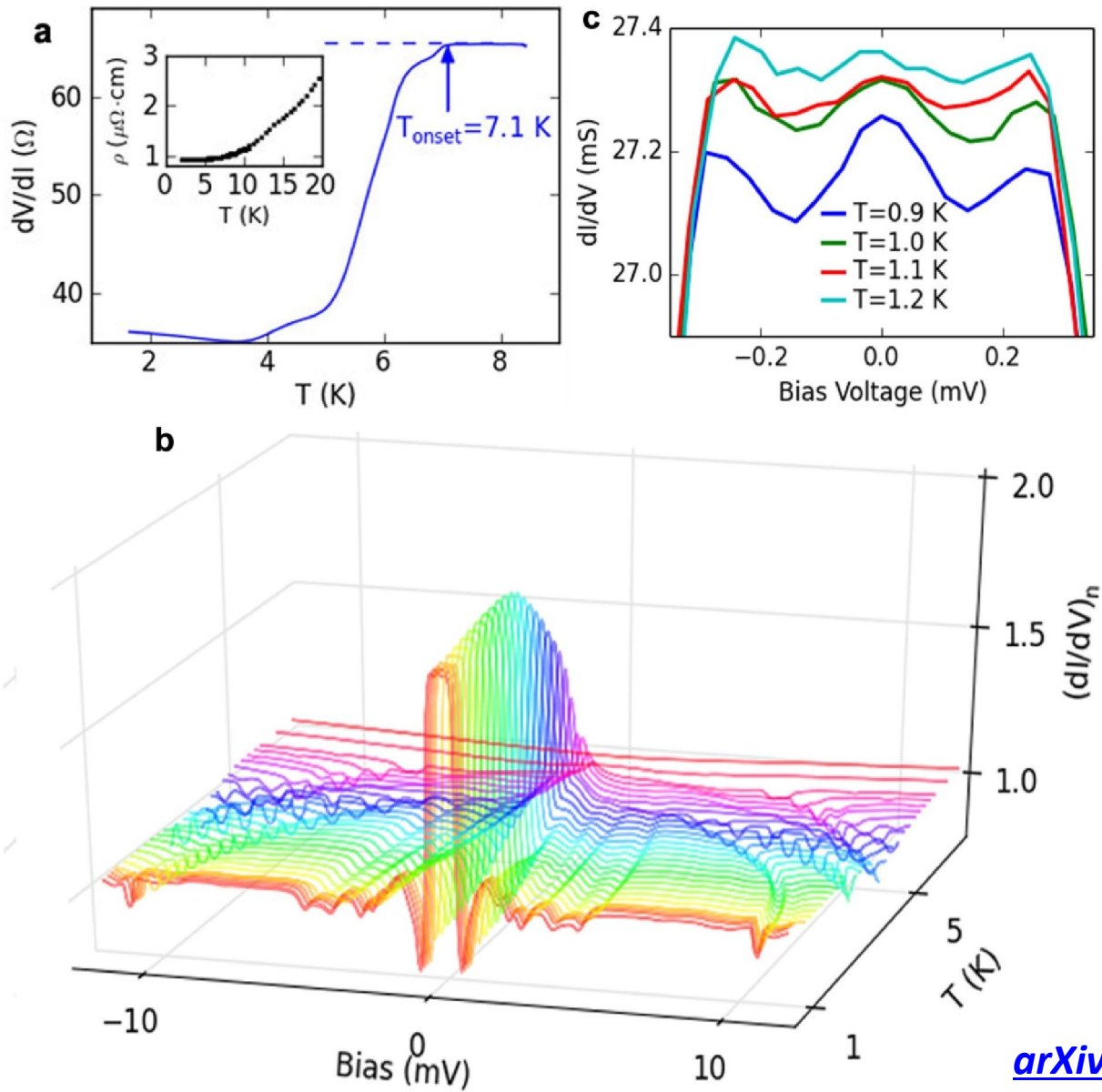


The applied magnetic field can suppress the observed gap.



Similar structure

## The data from Sample 2:



# Summary

- 1. By point contact measurement using “needle-anvil” configuration we firstly observe the unexpected superconducting behavior in 3D Dirac semimetal  $\text{Cd}_3\text{As}_2$  crystal.**
- 2. The observed ZBCP and DCPs features in PCS indicate the superconductivity we found is unconventional.**
- 3. Our further theoretical analyses reveal that the exotic features may originate from topological superconductivity in the surface FAS and bulk states.**
- 4. So far, most experiments are still focused on demonstrating or exploring the existence of topological superconductors. Our discovery of superconductivity in 3D Dirac semimetal which is of ultrahigh mobility may offer an ideal candidate or platform for studying topological superconductivity.**

**[arXiv:1501.00418](https://arxiv.org/abs/1501.00418)**

# Welcome to Jian Wang's Lab at Peking University:

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<http://www.phy.pku.edu.cn/icqmjianwanggroup/index.html>

探头



PhD Students:



Yanfei Zhao



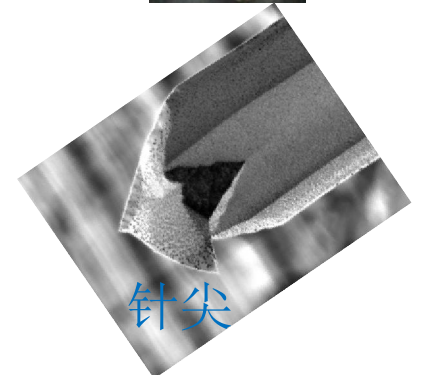
Huichao  
Wang



Ying Xing



**16 T, 50 mK Transport Measurement  
+AFM/MFM system  
Angle-dependent measurements and ETO**



针尖

## UHV MBE + Low temperature STM system



Yangwei Zhang



Yi Liu

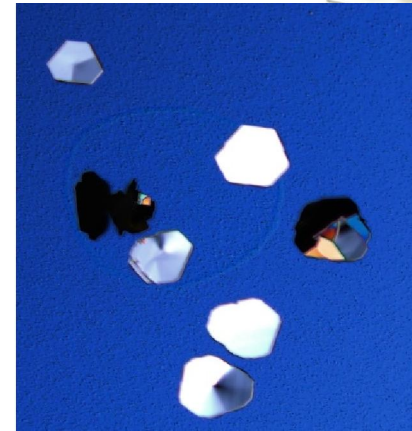




## Nanostructure sample growth (CVD):



Huichao Wang



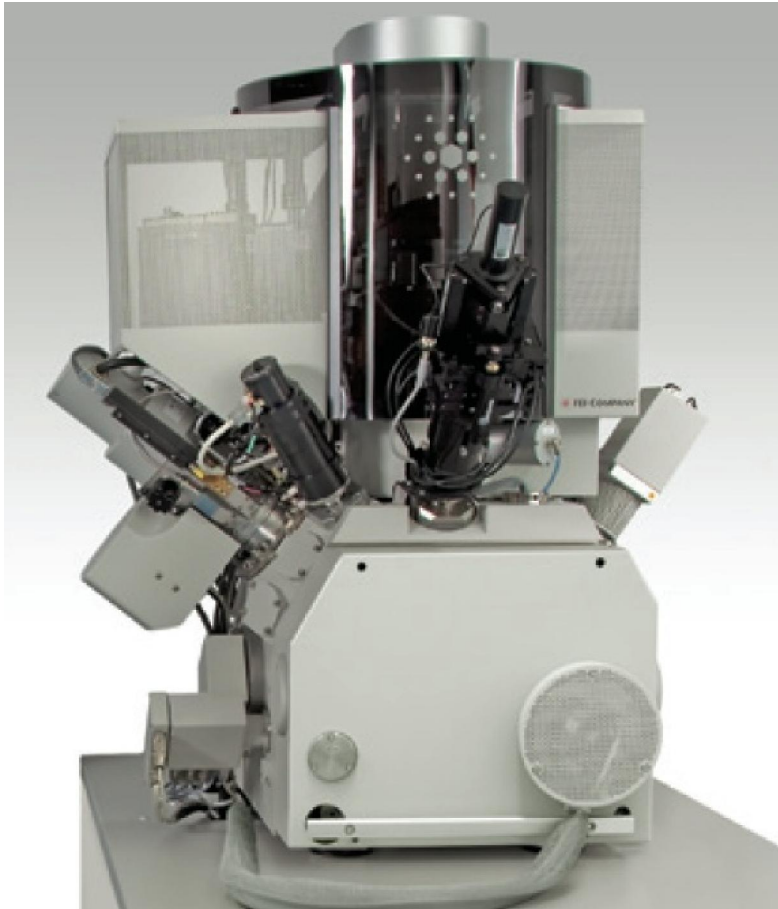
## Nanostructure sample growth (hydrothermal method):



Yangwei Zhang



Public Clean Room in our Center: Nano Fabrication by Helios 600i (FIB+EBL)



Masters:



**Yanfei Zhao**



**Ying Xing**

Welcome to Jian Wang's Group at Peking University:

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My Postdoc and PhD students:



Dr. Yi Sun



Yanfei Zhao



Huichao  
Wang



Ying Xing



Yangwei  
Zhang



Yi Liu

# THANK YOU !